500 mA 36V Input Low Supply Current LDO

NO. EA−304−230124

OUTLINE

R1517x is a CMOS-based LDO that specifically designed featuring 500 mA output current and 36 V input voltage. In addition to a conventional regulator circuit, R1517x consists of a constant slope circuit as a soft-start function, a fold-back protection circuit, a short current limit circuit, and a thermal shutdown circuit. Besides the low supply current by CMOS, the operating temperature is −40°C to 105°C and the maximum input voltage is 36 V, the R1517x is very suitable for power source of car accessories. R1517x supports the internal fixed output voltage type of R1517xxxxB/D/E/F, and the output voltage of R1517x001C can adjust the output voltage be set with an external resistor, and the setting range is from 2.5V to Max 20V. As for the soft-start time, R1517x is fixed internal in R1517xxxxB/C/D and is set to 120 µs (Typ). And the soft-start time in R1517xxxxE/F is adjustable by external capacitors. R1517x supports the auto-discharge function at standby in R1517xxxxD/F. R1517x is available in two packages for ultra-high wattage: HSOP-6J and TO-252-5-P2.

FEATURES

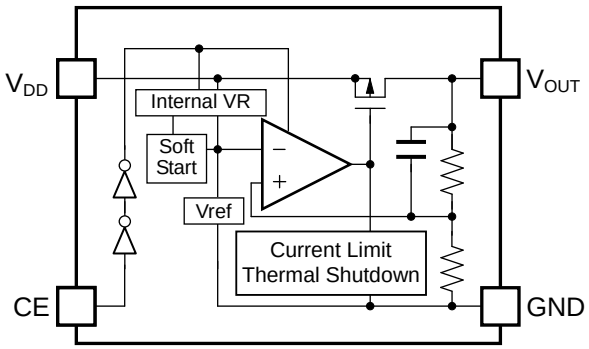
- Input Voltage Range (Maximum Rating) ····· 3.5 V to 36.0 V (50.0V)
- Operating Temperature Range ····· –40°C to 105°C
- Supply Current ····· Typ. 18 µA
- Standby Current ····· Typ. 0.1 µA
- Dropout Voltage ····· Typ. 0.35 V (I_{OUT} = 500 mA, V_{OUT} = 5.0 V)
- Output Voltage Accuracy ····· ±0.8% (V_{OUT} ≤ 5.0 V)
- Line Regulation ····· Typ. 0.01%/V
- Packages ····· HSOP-6J, TO-252-5-P2
- Output Voltage Range ····· R1517xxxxB/D/E/F: 2.5 V/3.3 V/3.4 V/5.0 V/ 8.5V
  R1517x001C: Adjustable from 2.5 V to 20.0 V with External Resistors.
  Feedback Voltage: 2.5 V
- Built-in Short Current Limit Circuit ····· Typ. 75 mA
- Built-in Fold-Back Protection Circuit ····· Min. 500 mA
- Built-in Thermal Shutdown Circuit ····· Typ. 160°C
- Built-in Soft-start Circuit ····· Typ.120 µs
  R1517xxxxE/F: Adjustable Time Setting with External Capacitors.
- Usable Ceramic Capacitors ····· R1517xxxxB/D/E/F: 0.1 µF or more
  R1517x001C: 1.0 µF or more

APPLICATIONS

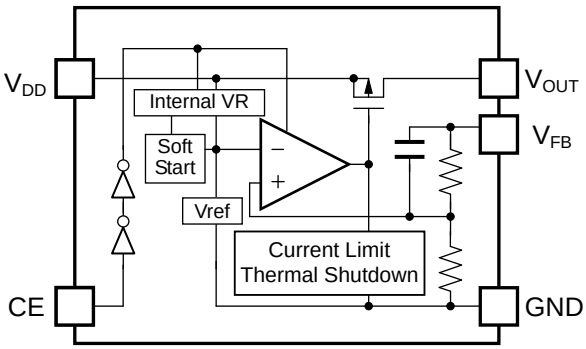
- Power source for home appliances such as refrigerators, rice cookers, electric water warmers.
- Power source for notebook PCs, digital TVs, telephones, private LAN systems.
- Power source for office equipment such as copiers, printers, facsimiles, scanners, and projectors

BLOCK DIAGRAMS

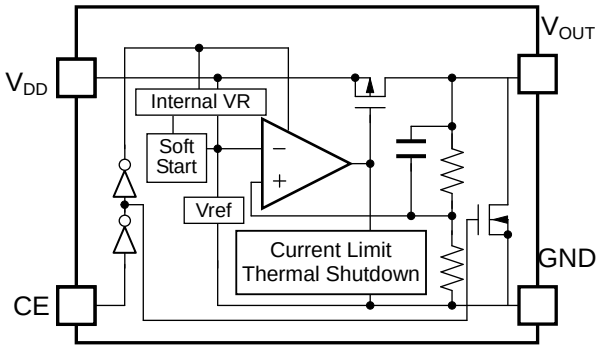
R1517xxxxB



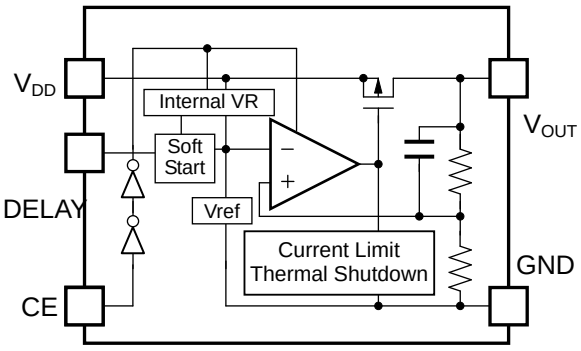
R1517x001C



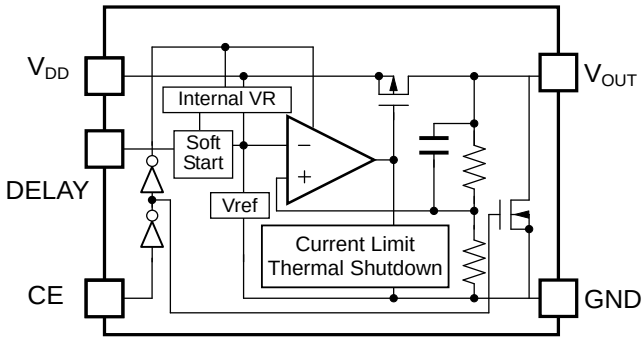
R1517xxxxD



R1517xxxxE



R1517xxxxF



SELECTION GUIDE

The output voltage, version, and package type for this device can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1517Sxx1∗-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes
R1517Jxx1∗-T1-FE	TO-252-5-P2	3,000 pcs	Yes	Yes

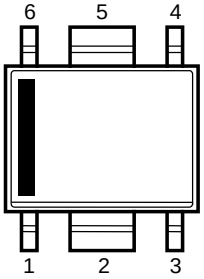
xx: Specify the set output voltage (V_{SET})
2.5 V (25) / 3.3 V (33) / 3.4 V (34) / 5.0 V (50) / 8.5 V (85)

Adjustable output voltage setting type is fixed to (00)
Note: R1517x001C-T1-#E only support

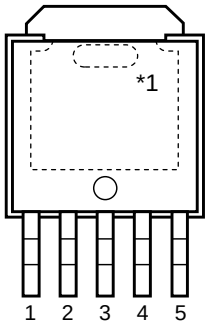
∗ : Specify the version with desired functions
B: No auto-discharge function
C: No auto-discharge function / Adjustable output voltage setting
D: Auto-discharge function
E: No auto-discharge function / Adjustable soft-start time setting
F: Auto-discharge function / Adjustable soft-start time setting

Auto-Discharge function quickly lowers the output voltage to 0 V by releasing the electrical charge in the external capacitor when the chip enable signal is switched from the active mode to the standby mode.

PIN DESCRIPTION



HSOP-6J



TO-252-5-P2

HSOP-6J

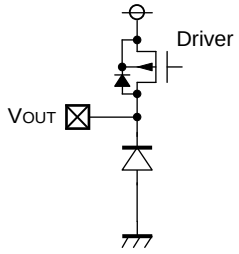
Pin No.	Symbol	Description	
1	V_{DD}	Input Pin	
2	GND	Ground Pin	
3	NC	No Connection	R1517SxxxB/D
	V_{FB}	Feedback Pin	R1517S001C
	DELAY	Soft-start Time Pin	R1517SxxxE/F
4	CE	Chip Enable Pin, Active-high	
5	GND	Ground Pin	
6	V_{OUT}	Output Pin	

TO-252-5-P2

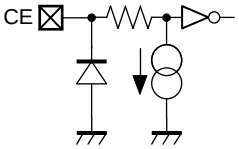
Pin No.	Symbol	Description	
1	V_{DD}	Input Pin	
2	NC	No Connection	R1517JxxxB/D
	V_{FB}	Feedback Pin	R1517J001C
	DELAY	Adjustable Soft-start Time Pin	R1517JxxxE/F
3	GND	Ground Pin	
4	CE	Chip Enable Pin, Active-high	
5	V_{OUT}	Output Pin	

*1 The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left open.

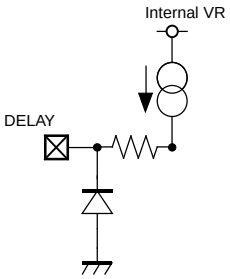
PIN EQUIVALENT CIRCUIT DIAGRAMS



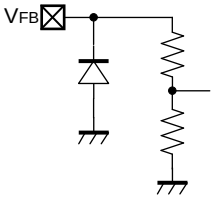
V_{OUT} Pin



CE Pin



DELAY Pin (R1517xxxxE/F)



V_{FB} Pin (R1517x001C)

ABSOLUTE MAXMUM RATINGS

Symbol	Item		Rating	Unit
V_{IN}	Input Voltage		−0.3 to 50	V
V_{IN}	Peak Input Voltage*1		60	V
V_{CE}	Input Voltage (CE Pin)		−0.3 to 50	V
V_{FB}	Input Voltage (V_{FB} Pin)		−0.3 to 50	V
V_{OUT}	Output Voltage		−0.3 to V_{IN} + 0.3 ≤ 50	V
P_D	Power Dissipation (HSOP-6J)*2	Standard Land Pattern	1700	mW
		Ultra High Wattage Land Pattern	2700	
	Power Dissipation (TO-252-5-P2)*2	Standard Land Pattern	1900	
		Ultra High Wattage Land Pattern	3800	
Ta	Operating Temperature Range		−40 to 105	°C
Tstg	Storage Temperature Range		−55 to 125	°C

*1 Duration time = 200 ms

*2 Refer to *PACKAGE INFORMATION* for detailed information.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

V_{IN} = V_{SET} + 1.0 V, I_{OUT} = 1 mA, C_{IN} = C_{OUT} = 0.1 µF, unless otherwise noted.
The specifications surrounded by ☐ are guaranteed by design engineering at -40°C ≤ Ta ≤ 105°C.

R1517xxxxB/D (Ta = 25°C)

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage			3.5		36	V
V_{OUT}	Output Voltage	Ta = 25°C	V_{SET} ≤ 5.0 V	×0.992		×1.008	V
			V_{SET} > 5.0 V	×0.99		×1.01	V
		−40°C ≤ Ta ≤ 105°C	V_{SET} ≤ 5.0 V	×0.982		×1.018	V
			V_{SET} > 5.0 V	×0.98		×1.02	V
ΔV_{OUT} /ΔI_{OUT}	Load Regulation	V_{IN} = V_{SET} + 2.0 V, 1mA ≤ I_{OUT} ≤ 250 mA		−15	3	25	mV
		V_{IN} = V_{SET} + 2.0 V, 1mA ≤ I_{OUT} ≤ 500 mA		−25	5	40	mV
V_{DIF}	Dropout Voltage	I_{OUT} = 500 mA		Refer to Product-specific Electrical Characteristics.			
I_{SS}	Supply Current	I_{OUT} = 0 mA			18	36	µA
Istandby	Standby Current	V_{CE} = 0 V			0.1	2.0	µA
ΔV_{OUT} /ΔV_{IN}	Line Regulation	V_{SET} + 0.5 V ≤ V_{IN} ≤ 36 V, Under the condition of V_{IN} ≥ 3.5 V			0.01	0.02	%/V
ΔV_{OUT} /ΔTa	Output Voltage Temperature Coefficient	−40°C ≤ Ta ≤ 105°C			±60		ppm /°C
I_{LIM}	Output Current Limit	V_{IN} = V_{SET} +2.0 V		500			mA
I_{SC}	Short Current Limit	V_{IN} = 5.0 V, V_{OUT} = 0 V			75		mA
I_{PD}	CE Pull-down Current	V_{CE} = 5.0 V			0.2	0.6	µA
		V_{CE} = 36 V			0.5	1.3	µA
t_{D1}	Soft-start Time 1				120		µs
V_{CEH}	CE Input Voltage "H"			2.2			V
V_{CEL}	CE Input Voltage "L"					1.0	V
T_{TSD}	Thermal Shutdown Temperature	Junction Temperature			160		°C
T_{TSR}	Thermal Shutdown Released Temperature	Junction Temperature			135		°C
R_{LOW}	Low Output Nch Tr. ON Resistance (R1517xxxxD)	V_{IN} = 14.0 V, V_{CE} = 0 V			3.2		kΩ

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj ≈ Ta = 25°C) except for Output Voltage Temperature Coefficient and Soft-start Time 1.

V_{IN} = V_{FB} (= 2.5 V) + 1.0 V = 3.5 V, I_{OUT} = 1 mA, C_{IN} = 0.1 µF, C_{OUT} = 1.0 µF, unless otherwise noted.
The specifications surrounded by ☐ are guaranteed by design engineering at -40°C ≤ Ta ≤ 105°C.

R1517x001C (Ta = 25°C)

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage		3.5		36	V
V_{FB}	Feedback Voltage	Ta = 25°C	2.480		2.520	V
		−40°C ≤ Ta ≤ 105°C	2.455		2.545	V
ΔV_{OUT} /ΔI_{OUT}	Load Regulation	V_{IN} = 4.5 V 1mA ≤ I_{OUT} ≤ 250 mA	−10	3	10	mV
		V_{IN} = 4.5 V 1 mA ≤ I_{OUT} ≤ 500 mA	−20	5	20	mV
V_{DIF}	Dropout Voltage	I_{OUT} = 500 mA			1.0	V
I_{SS}	Supply Current	I_{OUT} = 0 mA		18	36	µA
Istandby	Standby Current	V_{CE} = 0 V		0.1	2.0	µA
ΔV_{OUT} /ΔV_{IN}	Line Regulation	3.5 V ≤ V_{IN} ≤ 36 V		0.01	0.02	%/V
ΔV_{OUT} /ΔTa	Output Voltage Temperature Coefficient	−40°C ≤ Ta ≤ 105°C		±60		ppm /°C
I_{LIM}	Output Current Limit	V_{IN} = 4.5 V	500			mA
I_{SC}	Short Current Limit	V_{IN} = 5.0 V, V_{OUT} = V_{FB} = 0 V		75		mA
I_{PD}	CE Pull-down Current	V_{CE} = 5.0 V		0.2	0.6	µA
		V_{CE} = 36 V		0.5	1.3	µA
t_{D1}	Soft-start Time 1			120		µs
V_{CEH}	CE Input Voltage "H"		2.2			V
V_{CEL}	CE Input Voltage "L"				1.0	V
T_{TSD}	Thermal Shutdown Temperature	Junction Temperature		160		°C
T_{TSR}	Thermal Shutdown Released Temperature	Junction Temperature		135		°C

V_{OUT} = V_{FB} = 2.5 V (excluding short circuit current)
All test items listed under Electrical Characteristics are done under the pulse load condition (Tj ≈ Ta = 25°C) except for Output Voltage Temperature Coefficient Soft-start Time 1.

V_{IN} = V_{SET} + 1.0 V, I_{OUT} = 1 mA, C_{IN} = C_{OUT} = 0.1 µF, unless otherwise noted.

The specifications surrounded by [ ] are guaranteed by design engineering at -40°C ≤ Ta ≤ 105°C.

R1517xxxxE/F (Ta = 25°C)

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage			[3.5]		[36]	V
V_{OUT}	Output Voltage	Ta = 25°C	V_{SET} ≤ 5.0 V	×0.992		×1.008	V
			V_{SET} > 5.0 V	×0.99		×1.01	V
		−40°C ≤ Ta ≤ 125°C	V_{SET} ≤ 5.0 V	[×0.982]		[×1.018]	V
			V_{SET} > 5.0 V	[×0.98]		[×1.02]	V
ΔV_{OUT} /ΔI_{OUT}	Load Regulation	V_{IN} = V_{SET} +2.0 V 1 mA ≤ I_{OUT} ≤ 250 mA		[−15]	3	[25]	mV
		V_{IN} = V_{SET} +2.0 V 1 mA ≤ I_{OUT} ≤ 500 mA		[−25]	5	[40]	mV
V_{DIF}	Dropout Voltage	I_{OUT} = 500 mA		Refer to Product-specific Electrical Characteristics.			
I_{SS}	Supply Current	I_{OUT} = 0 mA			18	[36]	µA
Istandby	Standby Current	V_{CE} = 0 V			0.1	2.0	µA
ΔV_{OUT} /ΔV_{IN}	Line Regulation	V_{SET} +0.5 V ≤ V_{IN} ≤ 36 V, Under the condition of V_{IN} ≥ 3.5 V			0.01	[0.02]	%/V
ΔV_{OUT} /ΔTa	Output Voltage Temperature Coefficient	−40°C ≤ Ta ≤ 105°C			±60		ppm /°C
I_{LIM}	Output Current Limit	V_{IN} = V_{SET} +2.0 V		[500]			mA
I_{SC}	Short Current Limit	V_{IN} = 5.0 V, V_{OUT} = 0 V			75		mA
I_{PD}	CE Pull-down Current	V_{CE} = 5.0 V			0.2	[0.6]	µA
		V_{CE} = 36 V			0.5	[1.3]	µA
I_{DELAY}	DELAY Current	DELAY = GND		[1.5]	2.5	[3.5]	µA
t_{D1}	Soft-start Time 1	DELAY = OPEN			26		µs
t_{D2}	Soft-start Time 2	DELAY = 0.001 µF		210	290	415	µs
V_{CEH}	CE Input Voltage "H"			[2.2]			V
V_{CEL}	CE Input Voltage "L"					[1.0]	V
T_{TSD}	Thermal Shutdown Temperature	Junction Temperature			160		°C
T_{TSR}	Thermal Shutdown Released Temperature	Junction Temperature			135		°C
R_{LOW}	Low Output Nch Tr. ON Resistance (R1517xxx1F)	V_{IN} = 14.0 V, V_{CE} = 0 V			3.2		kΩ

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj ≈ Ta = 25°C) except for Output Voltage Temperature Coefficient, Soft-start Time 1, and Soft-start Time 2.

Product-specific Electrical Characteristics

The specifications surrounded by ☐ are guaranteed by design engineering at -40°C ≤ Ta ≤ 105°C.

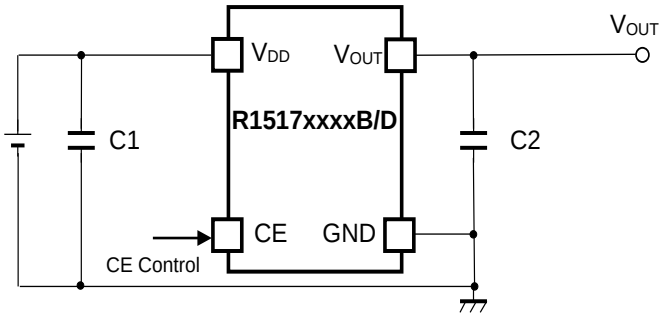
R1517xxx1B/D/E/F (Ta = 25°C)

Product Name	V_{OUT} [V] (Ta = 25°C)			V_{OUT} [V] (−40 ≤ Ta ≤ 105°C)			V_{DIF} [V]	
	Min.	Typ.	Max.	Min.	Typ.	Max.	Typ.	Max.
R1517x251x	2.480	2.500	2.520	2.455	2.500	2.545		1.00
R1517x331x	3.274	3.300	3.326	3.241	3.300	3.359	0.45	0.77
R1517x341x	3.373	3.400	3.427	3.339	3.400	3.461		
R1517x501x	4.960	5.000	5.040	4.910	5.000	5.090	0.35	0.62
R1517x851x	8.415	8.500	8.585	8.330	8.500	8.670	0.30	0.50

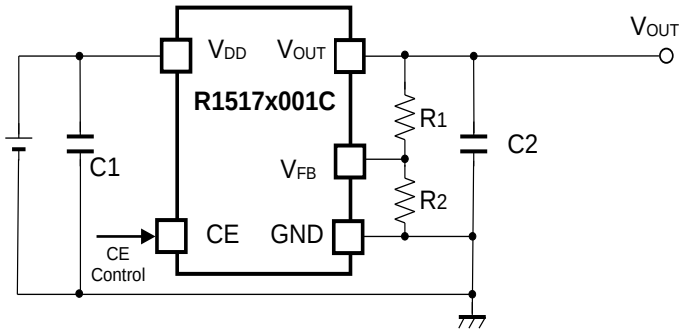
RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

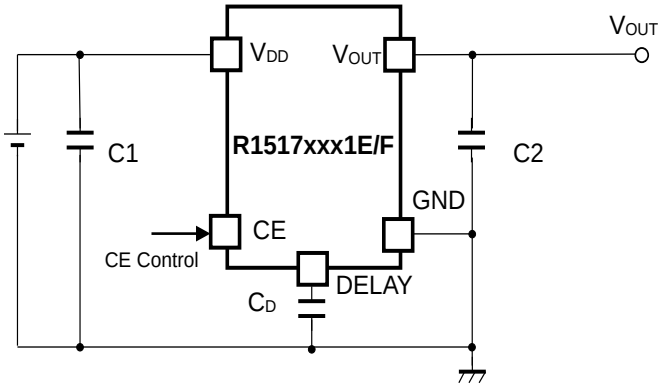
TYPICAL APPLICATION



R1517xxxxB/D Typical Application



R1517x001C Typical Application



R1517xxx1E/F Typical Application

External Components:

Symbol	Description
R1517xxxxB/D/E/F	
C1 (C_{IN})	0.1µF (Ceramic)
C2 (C_{OUT})	0.1µF (Ceramic)
R1517x001C	
C1 (C_{IN})	0.1µF (Ceramic)
C2 (C_{OUT})	1.0µF (Ceramic)

TECHNICAL NOTES

Phase Compensation

In LDO regulators, phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use the capacitor C2 of 0.1 µF or more (R1517xxxxB/D/E/F) / 1.0 µF or more (R1517x001C).

When using a tantalum type capacitor and the ESR (Equivalent Series Resistance) value is large, the output might be unstable. Evaluate the circuit including consideration of frequency characteristics.

For the externally adjustable output voltage type (R1517x001C), use 10 kΩ or lower resistance R2.

PCB Layout

Ensure the V_{DD} and GND lines are sufficiently robust. If their impedance is too high, noise pickup or unstable operation may result. Connect 0.1 µF or more of the capacitor C1 between the V_{DD} and GND, and as close as possible to the pins.

In addition, connect the capacitor C2 between V_{OUT} and GND, and as close as possible to the pins.

OPERATION DESCRIPTION

Thermal Shutdown Function

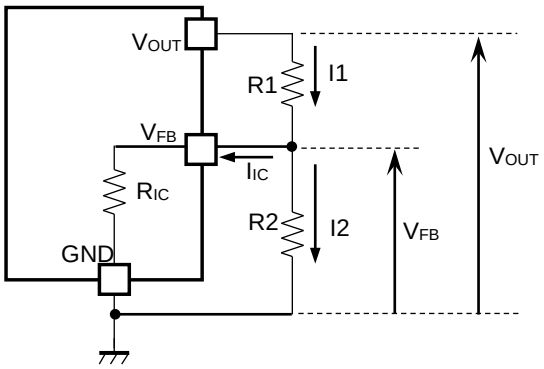
Thermal shutdown function is included in this device. If the junction temperature is more than or equal to 160°C (Typ.), the operation of the regulator would stop. After that, when the junction temperature is less than or equal to 135°C (Typ.), the operation of the regulator would restart. Unless the cause of rising temperature is removed, the regulator repeats on and off, and output waveform would be like consecutive pulses.

Adjustable Output Voltage Setting (R1517x001C)

The output voltage of R1517x001C can be adjusted by using the external divider resistors (R1, R2). By using the following equation, the output voltage (V_{OUT}) can be determined. The voltage which is fixed inside the IC is described as V_{FB}.

$$V_{OUT} = V_{FB} \times ((R1 + R2) / R2)$$

Recommended Range: 2.5 V ≤ V_{OUT} ≤ 20.0 V
V_{FB} = 2.5 V



Output Voltage Adjustment Using External Divider Resistors (R1, R2)

R_{IC} of the R1517x001C is approximately Typ. 1.35 MΩ (Ta=25°C, guaranteed by design engineering). For better accuracy, setting R1 << R_{IC} reduces errors. The resistance value for R2 should be set to 10 kΩ or lower. It is easily affected by noises when setting the value of R1 and R2 larger, which makes the impedance of V_{FB} pin larger.
R_{IC} could be affected by the temperature, therefore evaluate the circuit taking the actual conditions of use into account when deciding the resistance values for R1 and R2.

Soft-start Function

R1517x is equipped with a constant slope circuit, which achieves a soft-start function. This circuit allows the output voltage to start up gradually when the CE is turned on. The constant slope circuit minimizes the inrush current at the start-up and also prevents the overshoot of the output voltage. For R1517xxxxB/C/D, the capacitor to create the start-up slope is built in this device that does not require any external components. The start-up time and the start-up slope angle are fixed inside the device. In R1517xxxxE/F, the soft-start time is adjustable by inserting the external capacitor to DELAY pin. By using the following equation, the relation between the soft-start time t_D [s] and DELAY pin capacitor C_D [F] is determined.

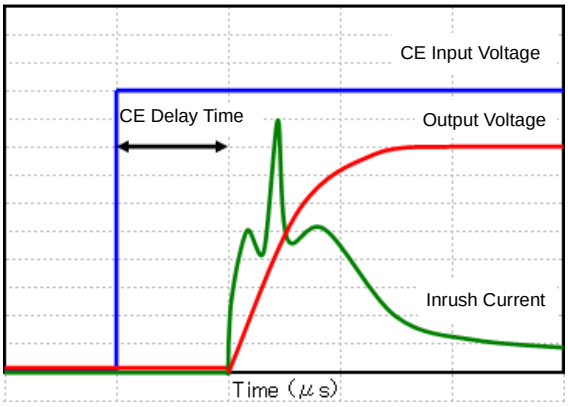
$$t_D = ((C_D + 90 \times 10^{-12}) / I_{DELAY}) \times 0.73$$

When the capacitor C_D is not used in R1517xxxxE/F, use the DELAY pin as OPEN. At that time, C_D = 0 in the above equation, therefore the start-up time is about 26 µs. However, be sure to consider approximately 50 µs of CE delay time.

The capacity (C_D) of the DELAY pin is discharged when V_{IN} is input and CE = L. If the C_D is restarted without being discharged, the soft start time may be shorter than the set time.

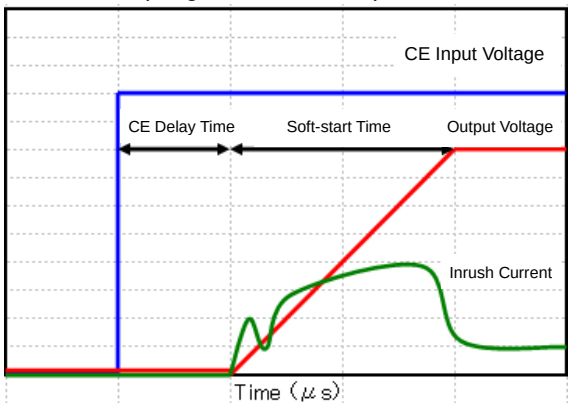
Conventional Inrush Current Limit Circuit

(Diagrammatic sketch)



Constant Slope Circuit

(Diagrammatic sketch)



PACKAGE INFORMATION

POWER DISSIPATION (HSOP-6J)

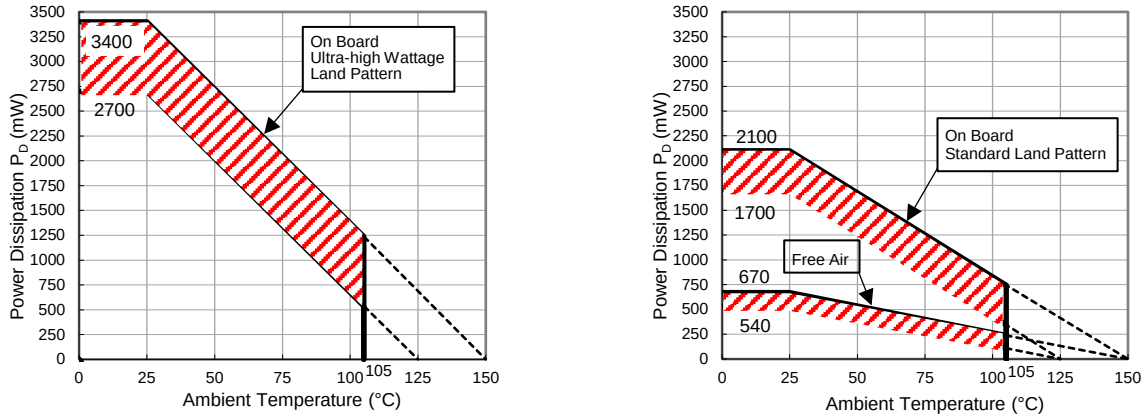
The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

Measurement Conditions

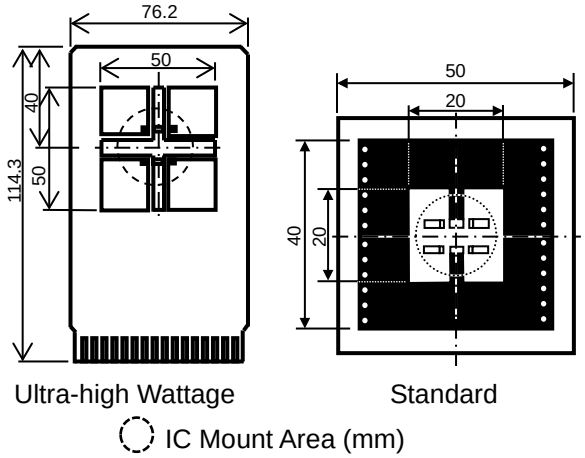
	Ultra-high Wattage Land Pattern	Standard Land Pattern
Environment	Mounting on Board (Wind Velocity = 0 m/s)	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-layer Board)	Glass Cloth Epoxy Plastic (Double-sided Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	50 mm × 50 mm × 1.6 mm
Copper Ratio	96%	50%
Through-holes	ϕ 0.3 mm × 28 pcs	ϕ 0.5 mm × 24 pcs

Measurement Result (Ta = 25°C, Tjmax = 125°C)

	Ultra-high Wattage Land Pattern	Standard Land Pattern	Free Air
Power Dissipation	2700 mW	1700 mW	540 mW
Thermal Resistance	37°C/W	59°C/W	185°C/W



Power Dissipation vs. Ambient Temperature

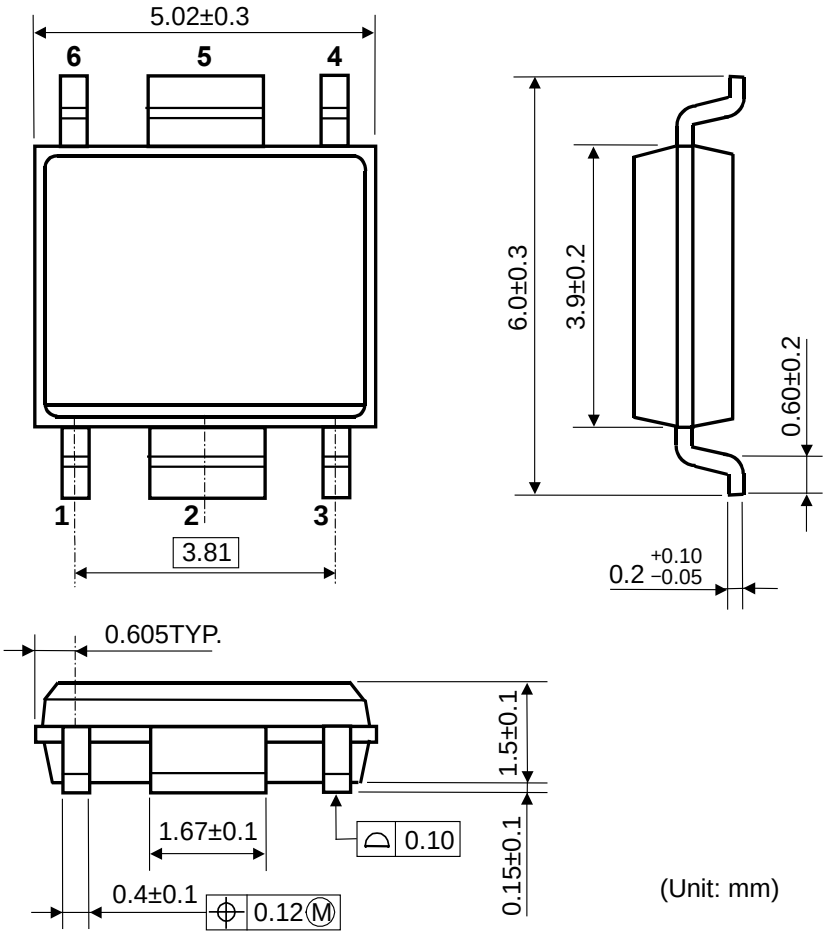


Measurement Board Pattern

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

PACKAGE DIMENSIONS (HSOP-6J)

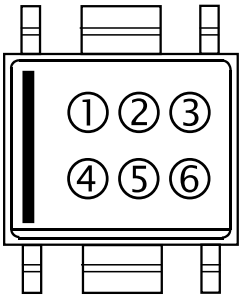


HSOP-6J Package Dimensions

MARK SPECIFICATION (HSOP-6J)

①②③④: Product Code … **Refer to *R1517S MARK SPECIFICATION TABLE***

⑤⑥: Lot Number … Alphanumeric Serial Number



HSOP-6J Mark Specification

R1517S MARK SPECIFICATION TABLE (HSOP-6J)

R1517Sxx1B

Product Name	①②③④	V_{SET}
R1517S252B	**V 1 2 5**	2.5 V
R1517S332B	**V 1 3 3**	3.3 V
R1517S342B	**V 1 3 4**	3.4 V
R1517S502B	**V 1 5 0**	5.0 V
R1517S852B	**V 1 8 5**	8.5 V

R1517S001C

Product Name	①②③④	V_{SET}
R1517S001C	**V 2 0 1**	–

R1517Sxx1D

Product Name	①②③④	V_{SET}
R1517S252D	**V 3 2 5**	2.5 V
R1517S332D	**V 3 3 3**	3.3 V
R1517S342D	**V 3 3 4**	3.4 V
R1517S502D	**V 3 5 0**	5.0 V
R1517S852D	**V 3 8 5**	8.5 V

R1517Sxx1E

Product Name	①②③④	V_{SET}
R1517S251E	**V 4 2 5**	2.5 V
R1517S331E	**V 4 3 3**	3.3 V
R1517S341E	**V 4 3 4**	3.4 V
R1517S501E	**V 4 5 0**	5.0 V
R1517S851E	**V 4 8 5**	8.5 V

R1517Sxx1F

Product Name	①②③④	V_{SET}
R1517S251F	**V 5 2 5**	2.5 V
R1517S331F	**V 5 3 3**	3.3 V
R1517S341F	**V 5 3 4**	3.4 V
R1517S501F	**V 5 5 0**	5.0 V
R1517S851F	**V 5 8 5**	8.5 V

POWER DISSIPATION (TO-252-5-P2)

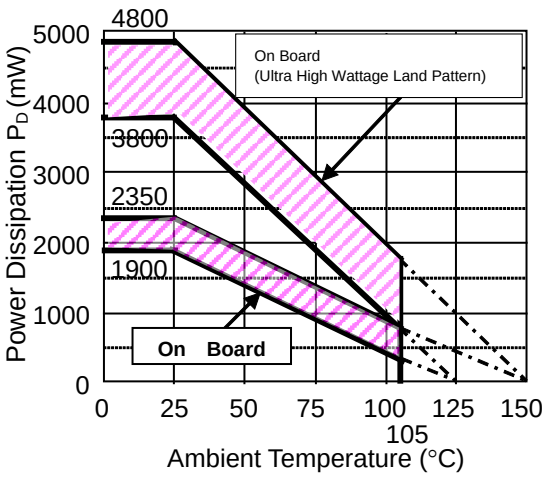
Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

Measurement Conditions

	Ultra High Wattage Land Pattern	Standard Land Pattern
Environment	Mounting on board (Wind velocity 0 m/s)	
Board Material	Glass cloth epoxy plastic (Four-layers)	Glass cloth epoxy plastic (Double layers)
Board Dimensions	76.2 mm x 114.3 mm x 0.8 mm	50 mm x 50 mm x 1.6 mm
Copper Ratio	Top, Back side: Approx. 96%, 2nd, 3rd: 100%	Top side: Approx. 50%, Back side: Approx. 50%
Through - hole	ϕ 0.4 mm x 30 pcs	ϕ 0.5 mm x 24 pcs

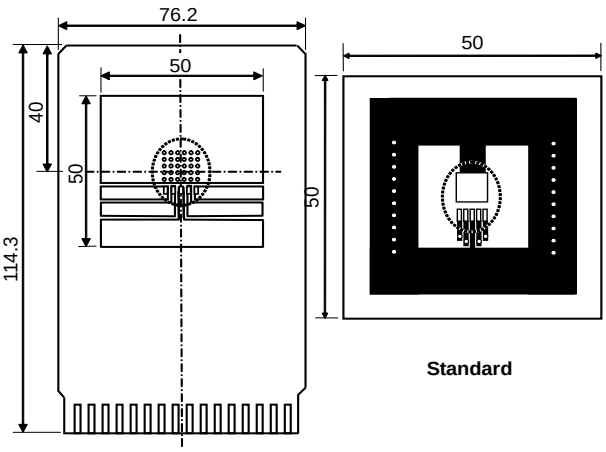
Measurement Result (Ta = 25°C, Tjmax = 125°C)

	Ultra High Wattage Land Pattern	Standard Land Pattern
Power Dissipation	3800 mW	1900 mW
Thermal Resistance	θja= (125-25°C)/3.8 W = 26°C/W	θja=(125-25°C)/1.9 W= 53°C/W
	θjc= 7°C/W	θjc= 17°C/W



Power Dissipation

Power Dissipation vs. Ambience Temperature



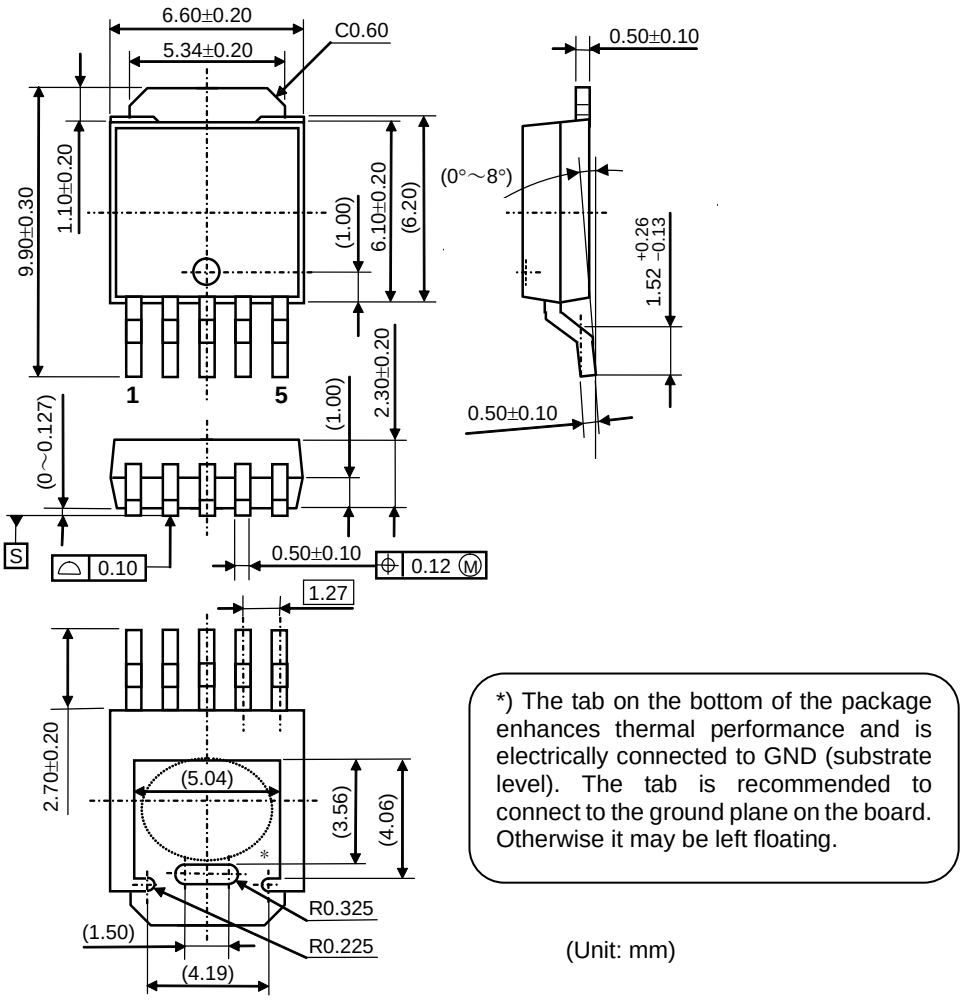
IC Mount Area (Unit: mm)

Measurement Board Pattern

The above graph shows the Power Dissipation of the package based on Tjmax=125°C and Tjmax=150°C. Operating the IC in the shaded area in the graph might have an influence it's lifetime. Operating time must be within the time limit described in the table below, in case of operating in the shaded area.

Operating Time	Estimated years(Operating four hours/day)
13,000 hours	9years

PACKAGE DIMENSIONS (TO-252-5-P2)



*) The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). The tab is recommended to connect to the ground plane on the board. Otherwise it may be left floating.

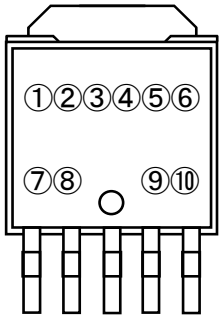
(Unit: mm)

TO-252-5-P2 Package Dimensions

MARK SPECIFICATION (TO-252-5-P2)

①②③④⑤⑥⑦⑧: Product Code … **Refer to *R1517J MARK SPECIFICATION TABLE***

⑨⑩: Lot Number … Alphanumeric Serial Number



TO-252-5-P2 Mark Specification

R1517J MARK SPECIFICATION TABLE (TO-252-5-P2)

R1517Jxx1B

Product Name	①②③④⑤⑥⑦⑧	V_{SET}
R1517J251B	**K 1 J 2 5 1 B**	2.5 V
R1517J331B	**K 1 J 3 3 1 B**	3.3 V
R1517J341B	**K 1 J 3 4 1 B**	3.4 V
R1517J501B	**K 1 J 5 0 1 B**	5.0 V
R1517J851B	**K 1 J 8 5 1 B**	8.5 V

R1517J001C (Adjustable Output Voltage Setting Type)

Product Name	①②③④⑤⑥⑦⑧	V_{SET}
R1517J001C	**K 2 J 0 0 1 C**	—

R1517Jxx1D

Product Name	①②③④⑤⑥⑦⑧	V_{SET}
R1517J251D	**K 3 J 2 5 1 D**	2.5 V
R1517J331D	**K 3 J 3 3 1 D**	3.3 V
R1517J341D	**K 3 J 3 4 1 D**	3.4 V
R1517J501D	**K 3 J 5 0 1 D**	5.0 V
R1517J851D	**K 3 J 8 5 1 D**	8.5 V

R1517Jxx1E

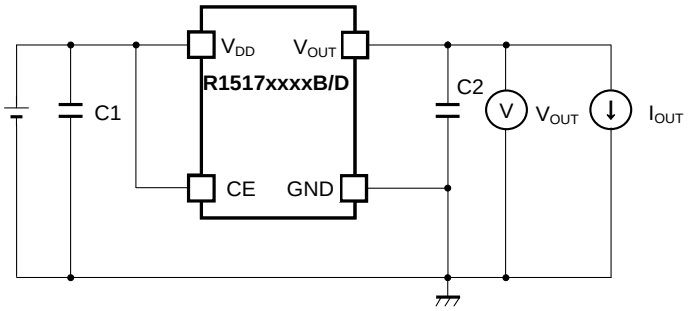
Product Name	①②③④⑤⑥⑦⑧	V_{SET}
R1517J251E	**K 4 J 2 5 1 E**	2.5 V
R1517J331E	**K 4 J 3 3 1 E**	3.3 V
R1517J341E	**K 4 J 3 4 1 E**	3.4 V
R1517J501E	**K 4 J 5 0 1 E**	5.0 V
R1517J851E	**K 4 J 8 5 1 E**	8.5 V

R1517Jxx1F

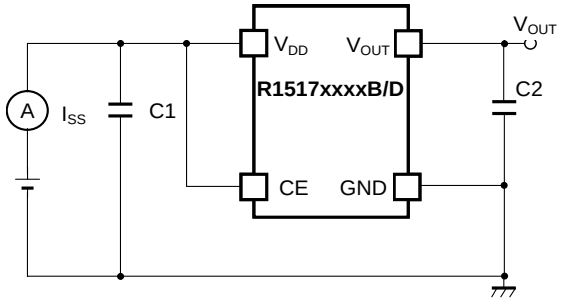
Product Name	①②③④⑤⑥⑦⑧	V_{SET}
R1517J251F	**K 5 J 2 5 1 F**	2.5 V
R1517J331F	**K 5 J 3 3 1 F**	3.3 V
R1517J341F	**K 5 J 3 4 1 F**	3.4 V
R1517J501F	**K 5 J 5 0 1 F**	5.0 V
R1517J851F	**K 5 J 8 5 1 F**	8.5 V

TEST CIRCUITS

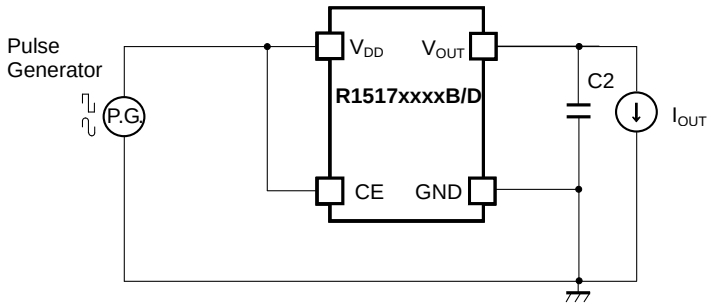
Soft-start Internal Fixed Type (R1517xxxxB/D)



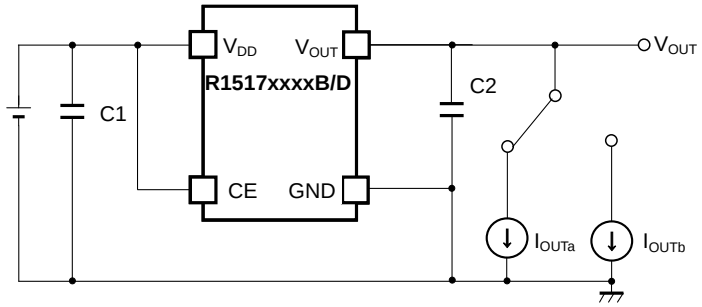
R1517xxxxB/D Basic Test Circuit



R1517xxxxB/D Supply Current Test Circuit

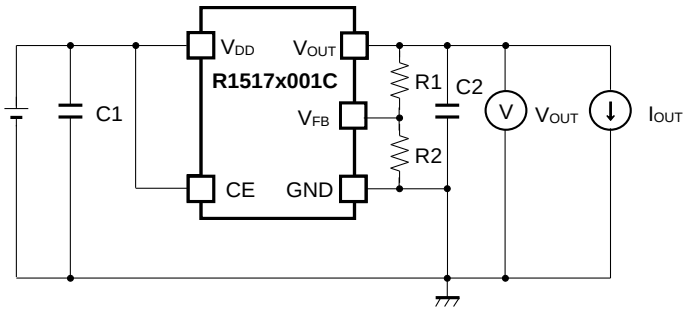


R1517xxxxB/D Ripple Rejection Test Circuit

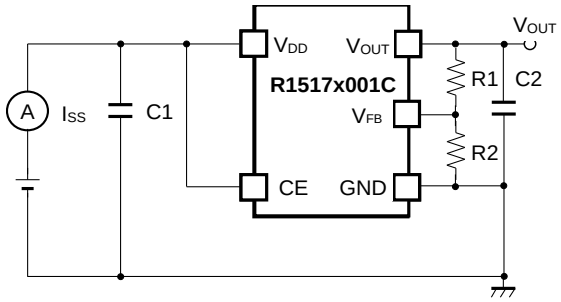


R1517xxxxB/D Load Transient Response Test Circuit

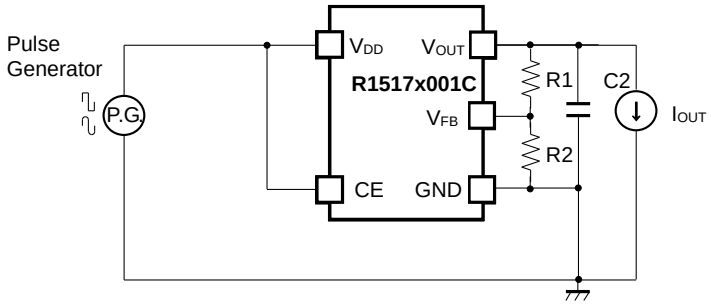
Adjustable Output Voltage Setting Type (R1517x001C)



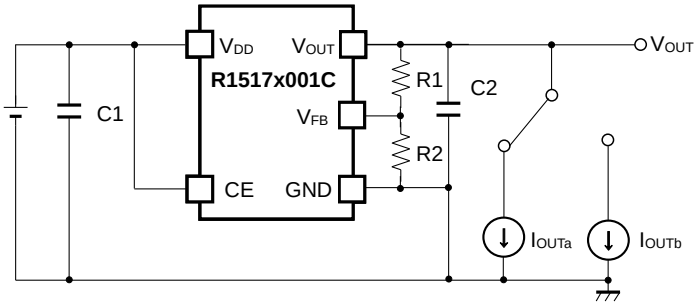
R1517x001C Basic Test Circuit



R1517x001C Supply Current Test Circuit



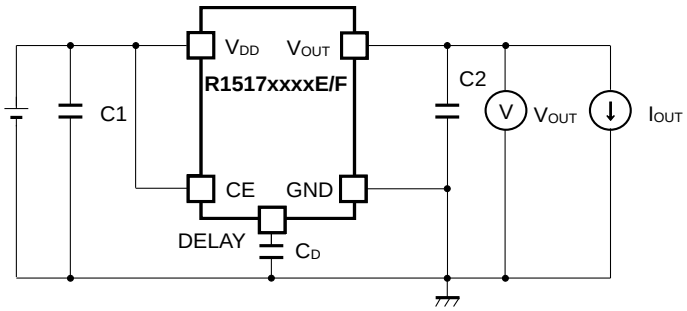
R1517x001C Ripple Rejection Test Circuit



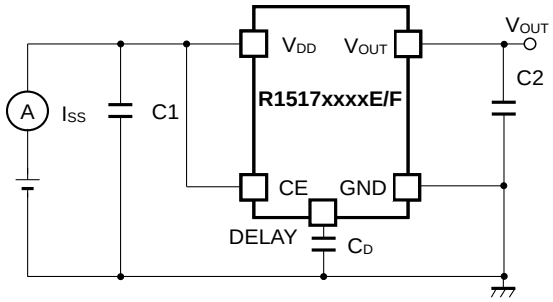
R1517x001C Load Transient Response Test Circuit

Note: Refer to *Adjustable Output Voltage Setting* for R1 and R2.

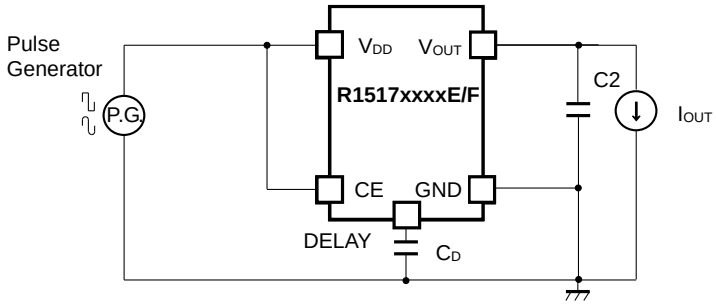
Adjustable Soft-start Setting Type (R1517xxxxE/F)



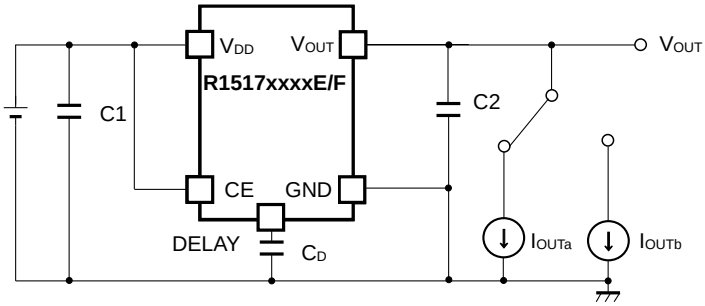
R1517xxxxE/F Basic Test Circuit



R1517xxxxE/F Supply Current Test Circuit



R1517xxxxE/F Ripple Rejection Test Circuit



R1517xxxxE/F Load Transient Response Test Circuit

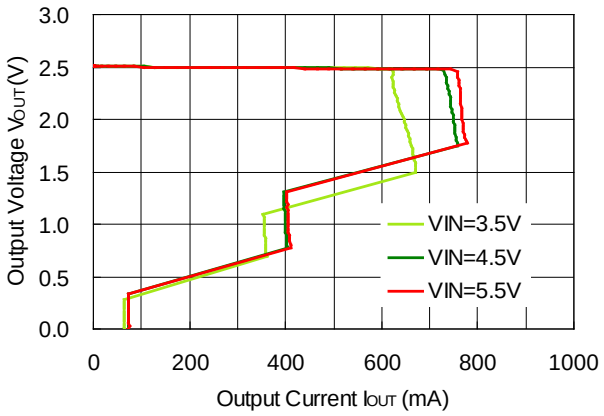
Note: Refer to *Soft-start Function* for detailed information on C_D.

TYPICAL CHARACTERISTICS

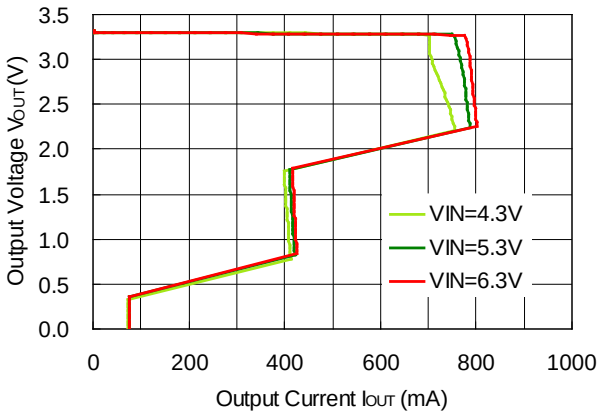
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Output Voltage vs. Output Current (Ta = 25°C)

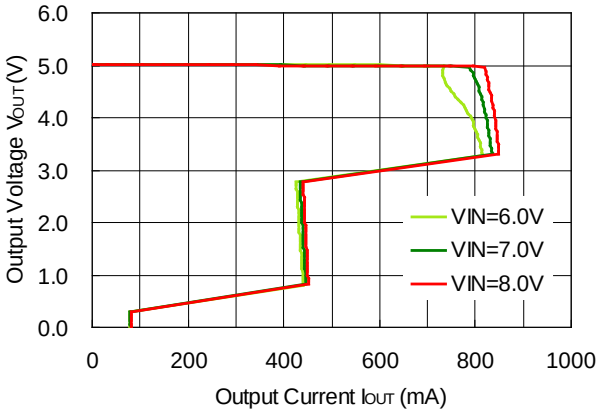
R1517x25xx, R1517x001C



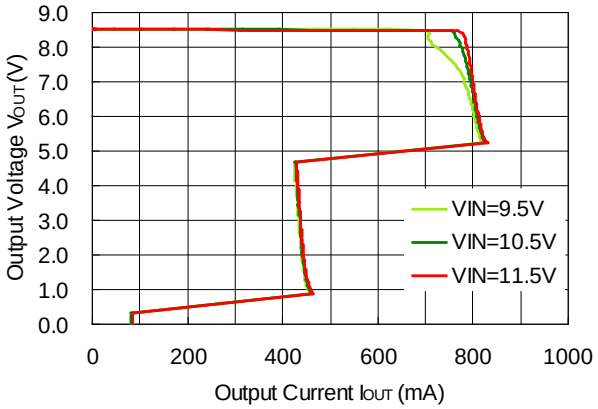
R1517x33xx



R1517x50xx

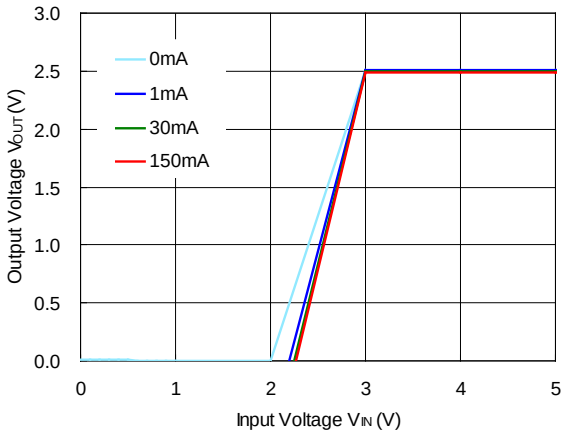


R1517x85xx

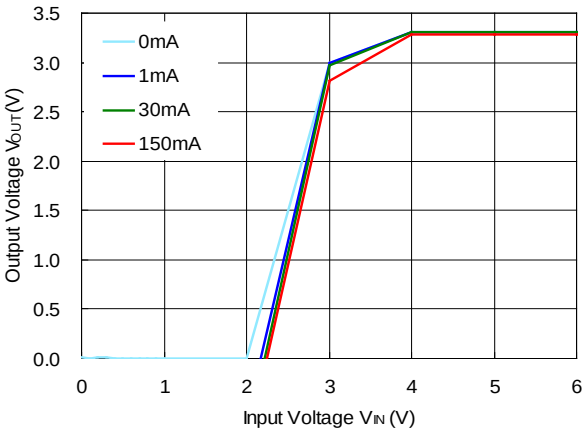


2) Output Voltage vs. Input Voltage (Ta = 25°C)

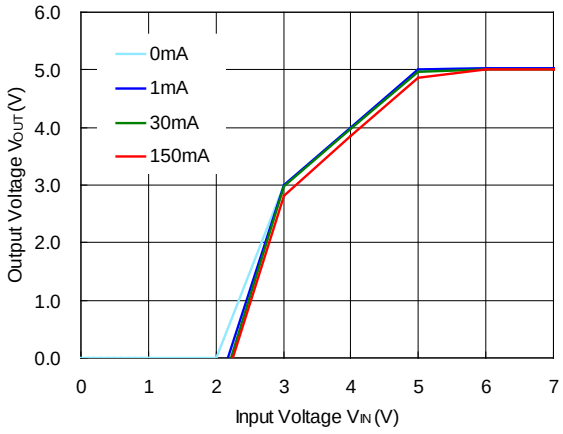
R1517x25xx



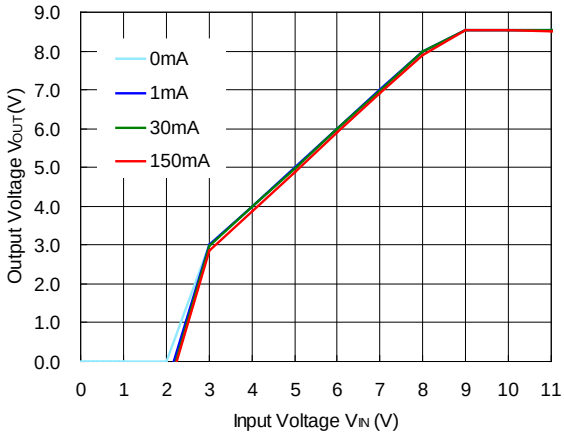
R1517x33xx



R1517x50xx

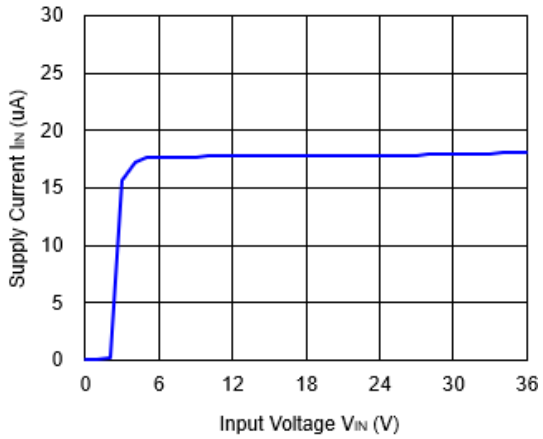


R1517x85xx

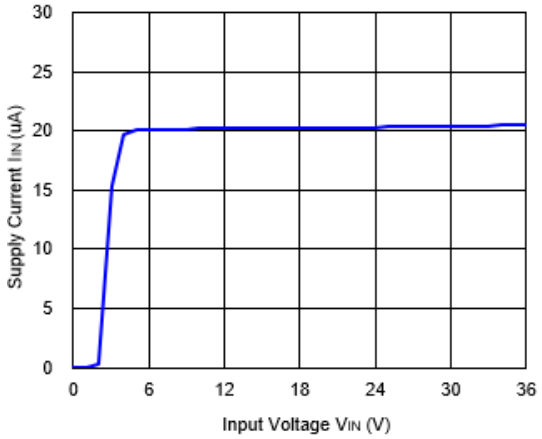


3) Supply Current vs. Input Voltage （ I_{OUT} = 0 mA ）

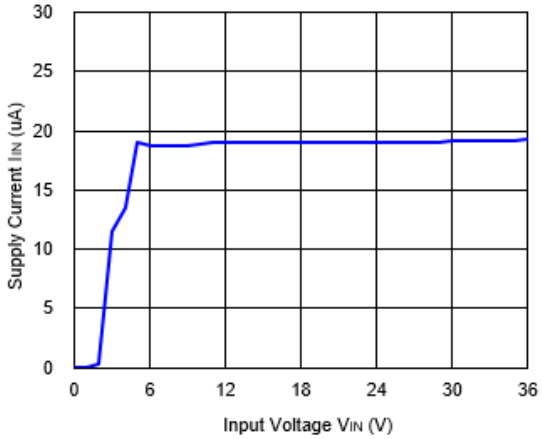
R1517x25xx, R1517x001C



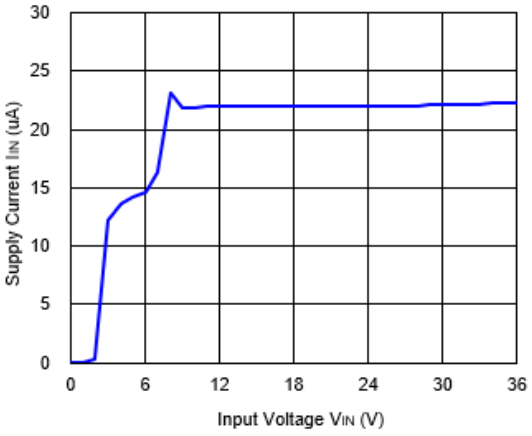
R1517x33xx



R1517x50xx

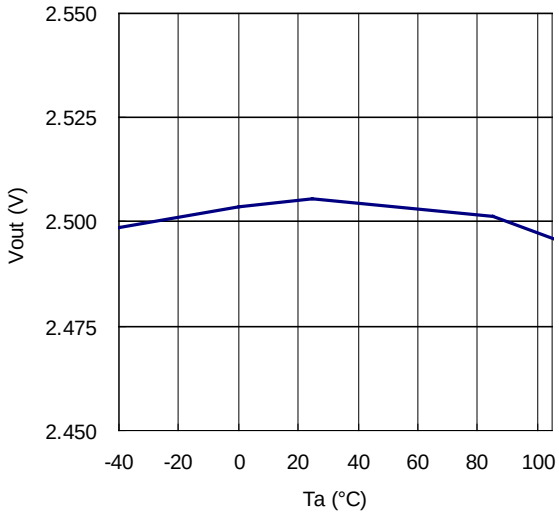


R1517x85xx

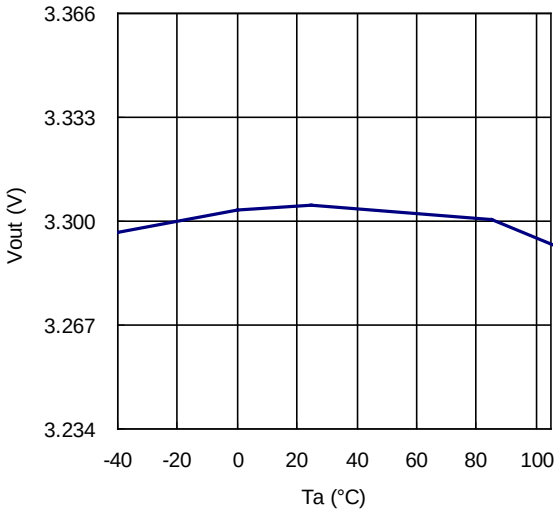


4) Output Voltage vs. Operating Temperature

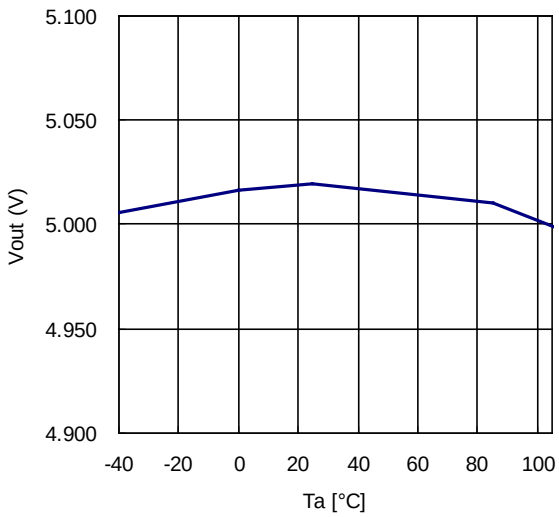
R1517x25xx, R1517x001C



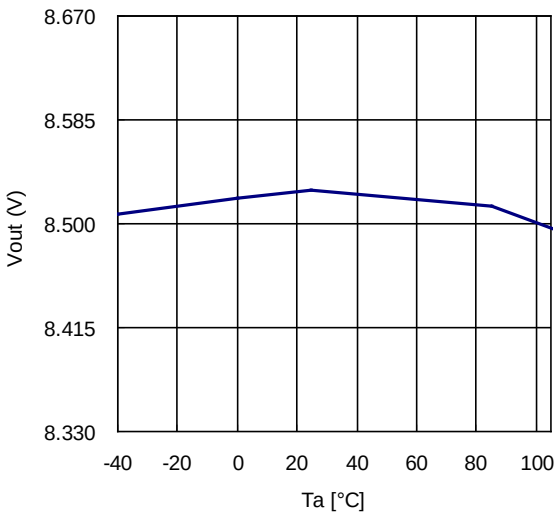
R1517x33xx



R1517x50xx

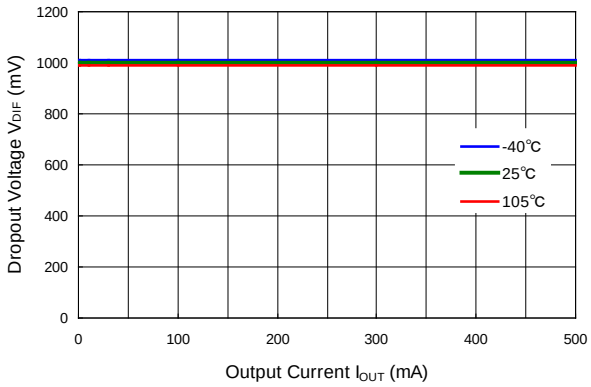


R1517x85xx

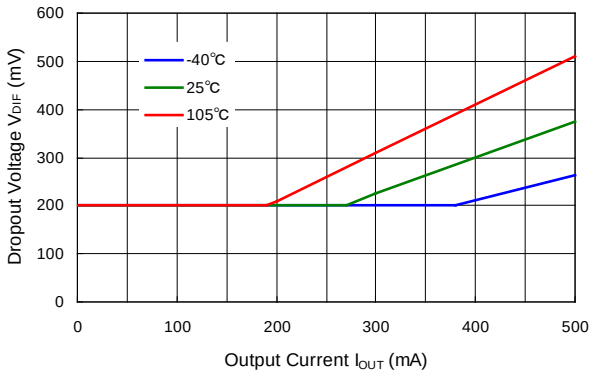


5) Dropout Voltage vs. Output Current

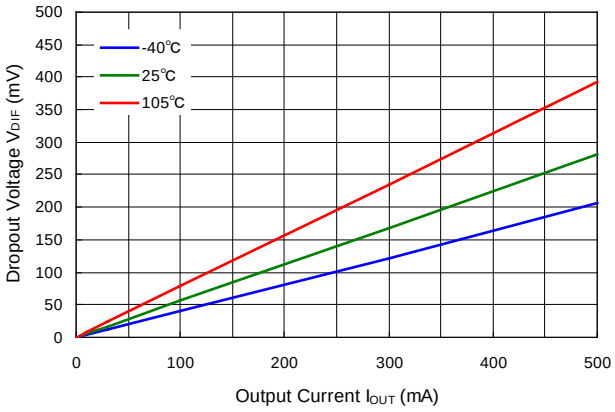
R1517x25xx, R151x001C



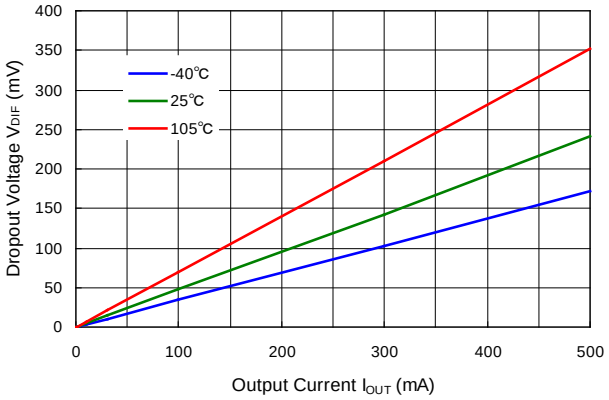
R1517x33xx



R1517x50xx

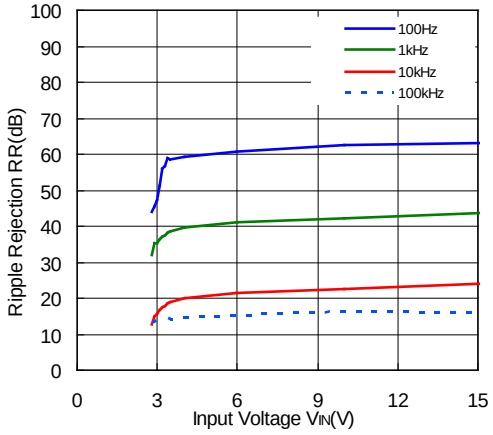


R1517x85xx

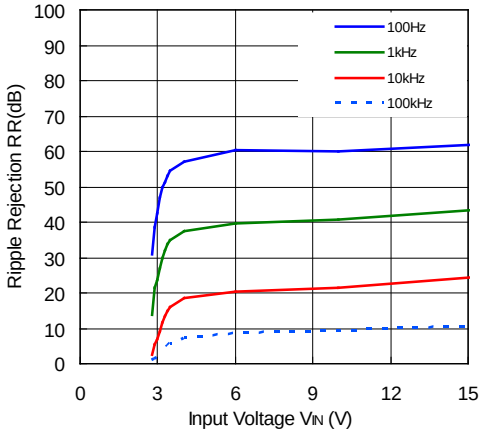


6) Ripple Rejection vs. Input Voltage (Ta = 25°C, Ripple = 0.2 Vpp)

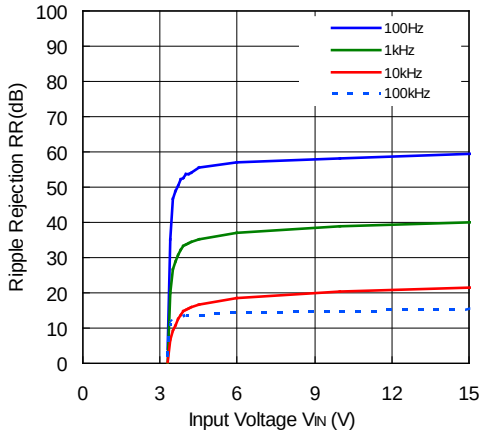
R1517x25xx, R1517x001C (I_{OUT} = 1 mA)



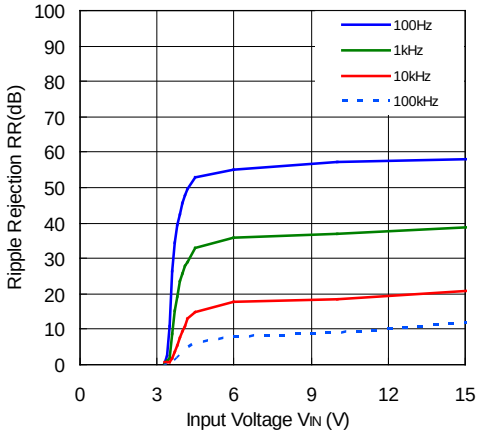
R1517x25xx, R1517x001C (I_{OUT} = 150 mA)



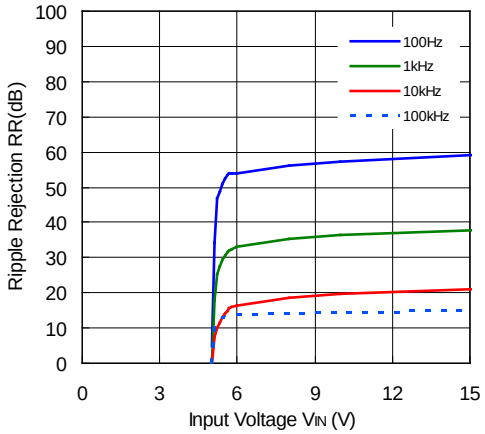
R1517x33xx (I_{OUT} = 1 mA)



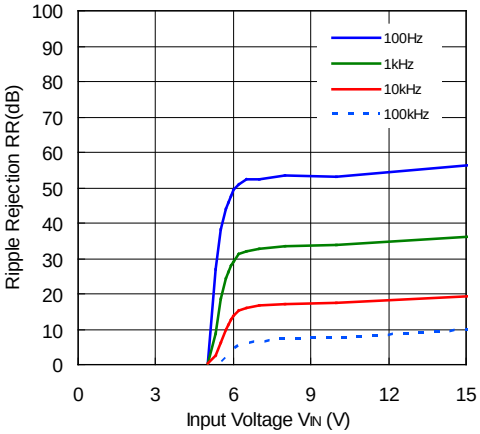
R1517x33xx (I_{OUT} = 150 mA)



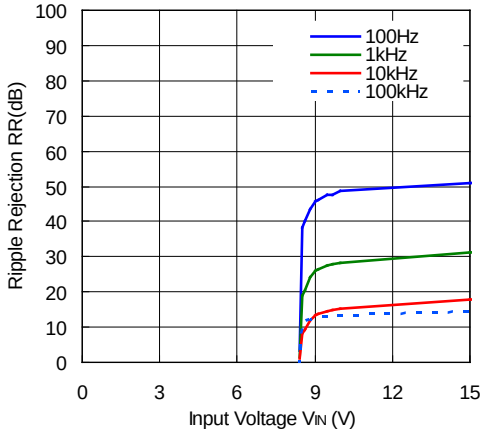
R1517x50xx (I_{OUT} = 1 mA)



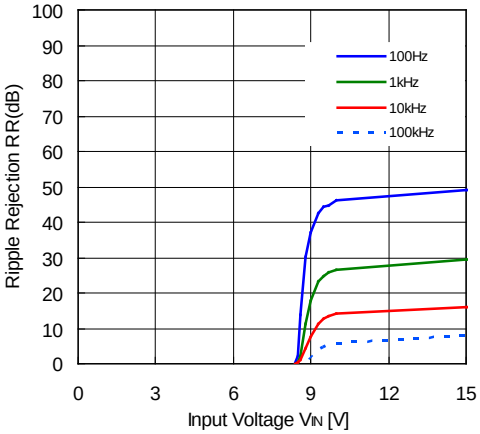
R1517x50xx (I_{OUT} = 150 mA)



R1517x85xx (I_{OUT} = 1 mA)

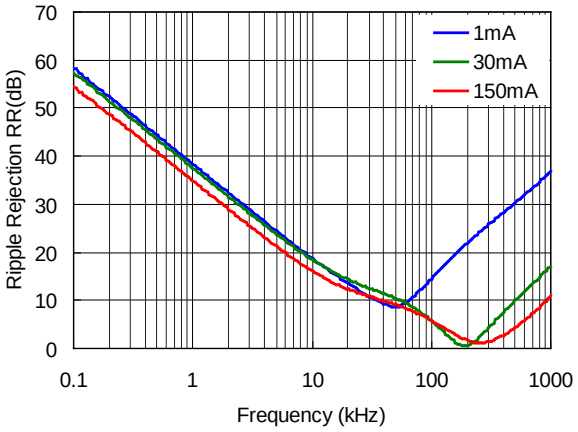


R1517x85xx (I_{OUT} = 150 mA)

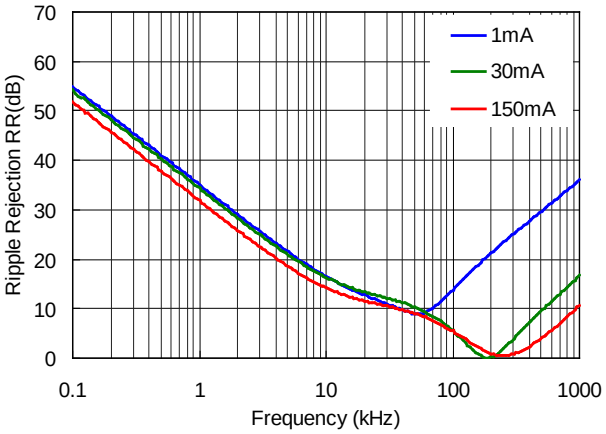


7) Ripple Rejection vs. Frequency (Ta = 25°C, Ripple = 0.2 Vpp)

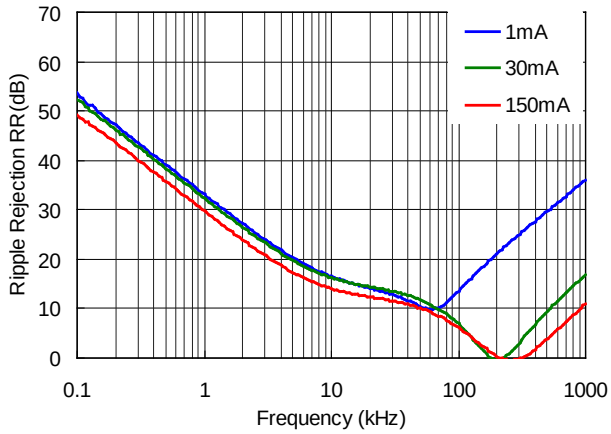
R1517x25xx, R1517x001C



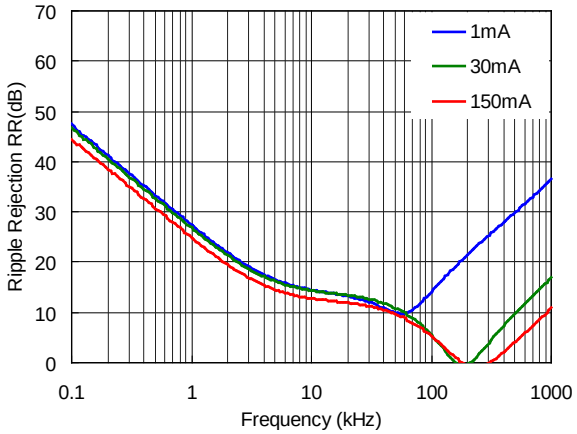
R1517x33xx



R1517x50xx

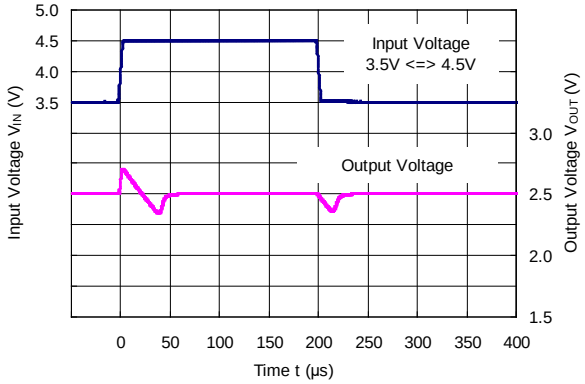


R1517x85xx

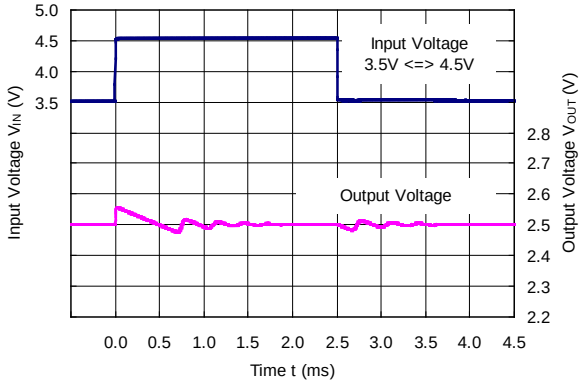


8) Input Transient Response (Ta = 25°C, I_{OUT} = 1 mA, tr = tf = 5 µs)

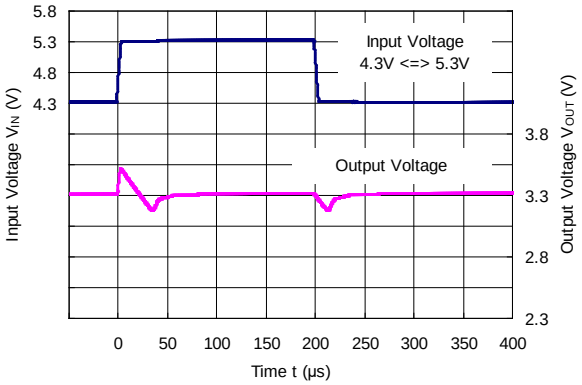
R1517x25xx, R1517x001C (C2 = 0.1 µF)



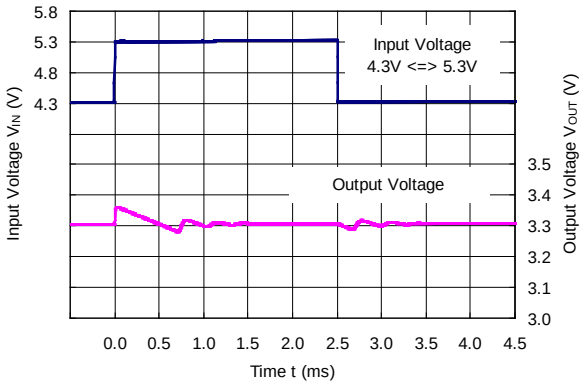
R1517x25xx, R1517x001C (C2 = 10 µF)



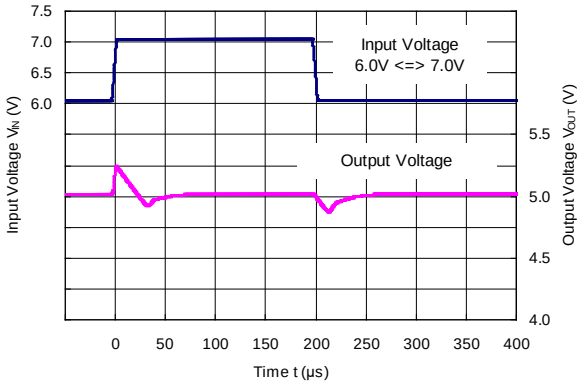
R1517x33xx (C2 = 0.1 µF)



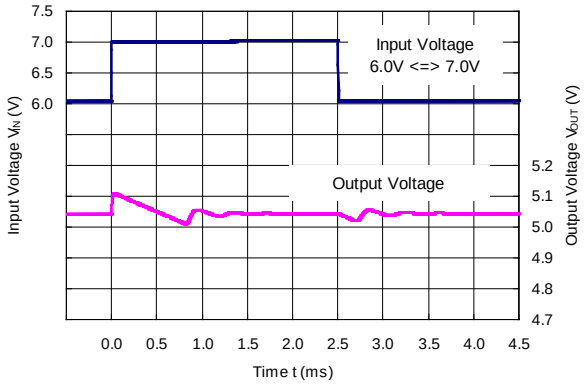
R1517x33xx (C2 = 10 µF)



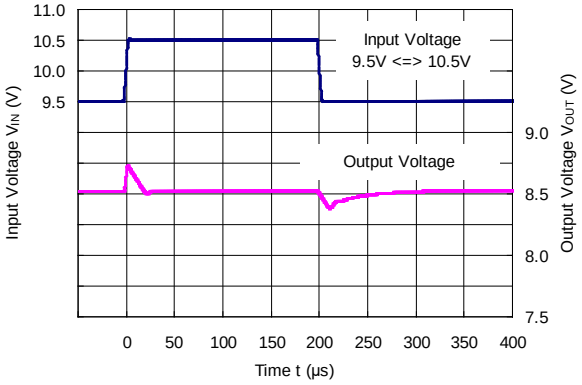
R1517x50xx (C2 = 0.1 µF)



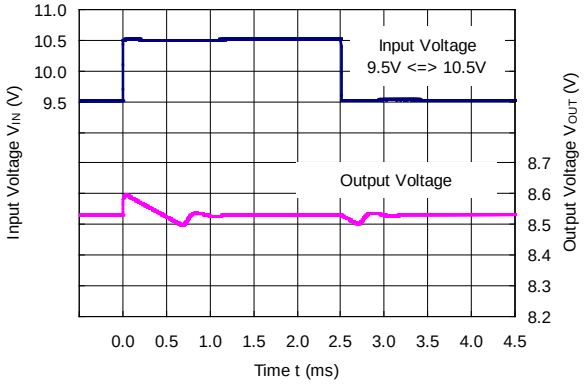
R1517x50xx (C2 = 10 µF)



R1517x85xx (C2 = 0.1 µF)

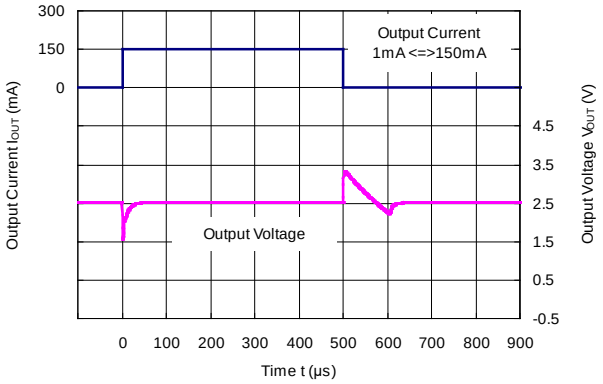


R1517x85xx (C2 = 10 µF)

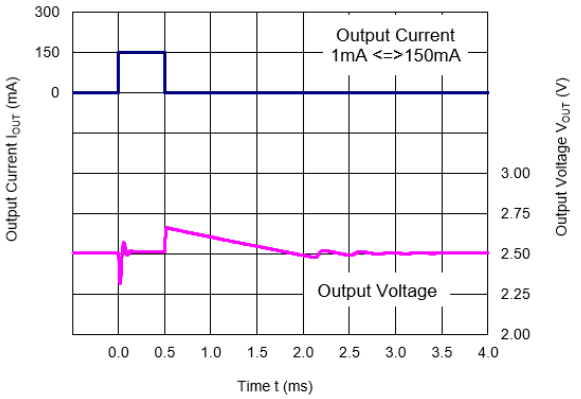


9) Load Transient Response (Ta = 25°C, V_{IN} = V_{OUT} + 1.0 V, tr = tf = 0.5 µs)

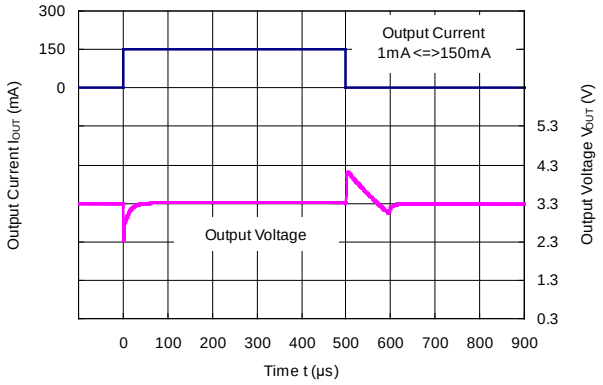
R1517x25xx, R1517x001C (C2 = 0.1 µF)



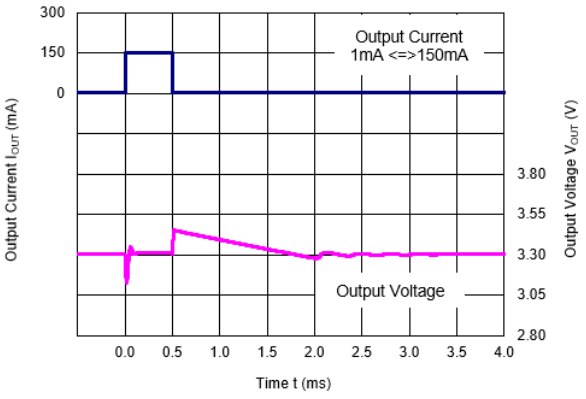
R1517x25xx, R1517x001C (C2 = 10 µF)



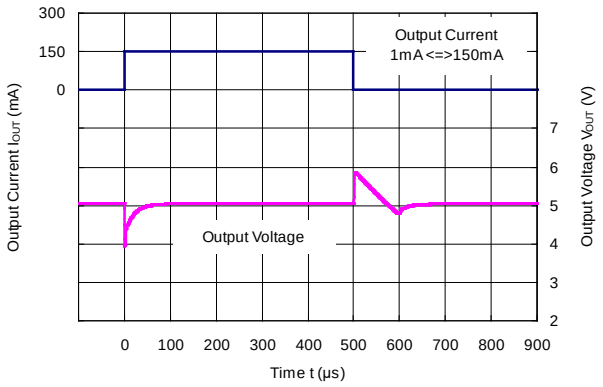
R1517x33xx (C2 = 0.1 µF)



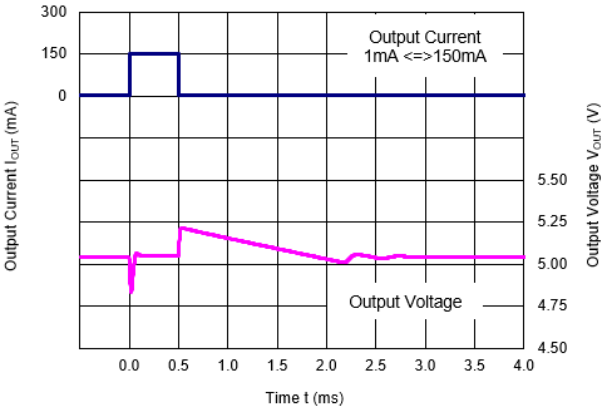
R1517x33xx (C2 = 10 µF)



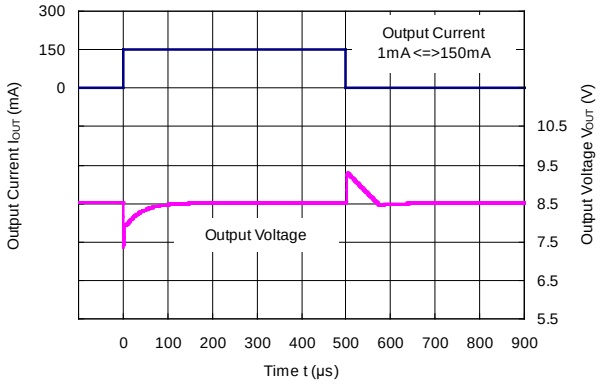
R1517x50xx (C2 = 0.1 µF)



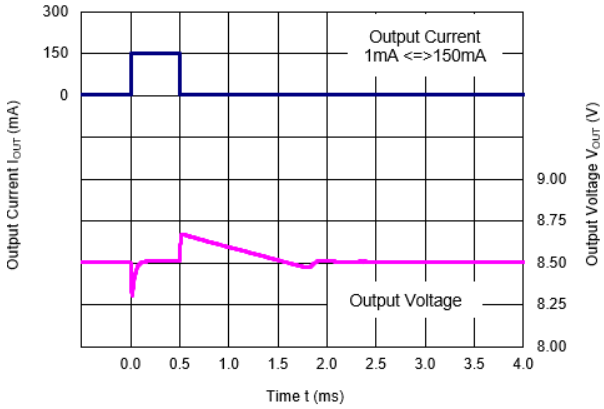
R1517x50xx (C2 = 10 µF)



R1517x85xx (C2 = 0.1 µF)

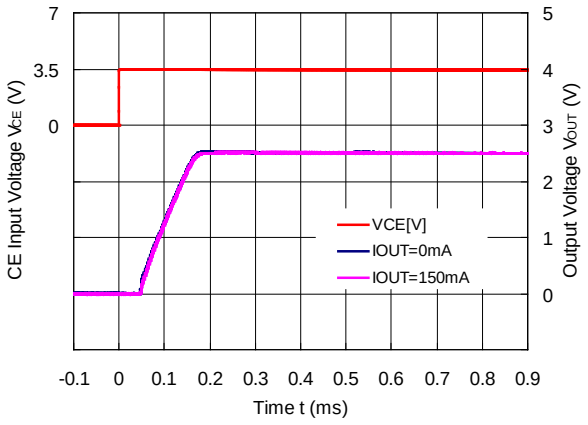


R1517x85xx (C2 = 10 µF)

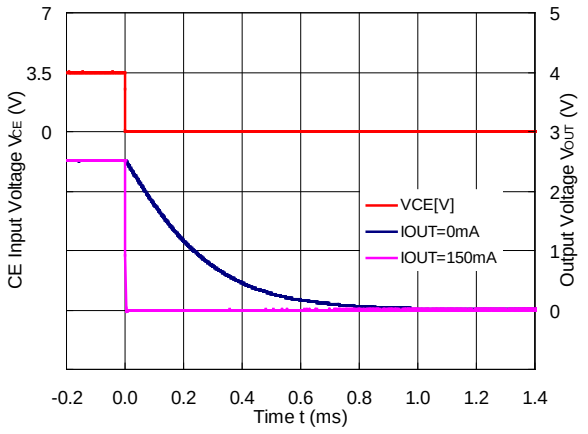


10) CE Transient Response (Ta = 25°C)

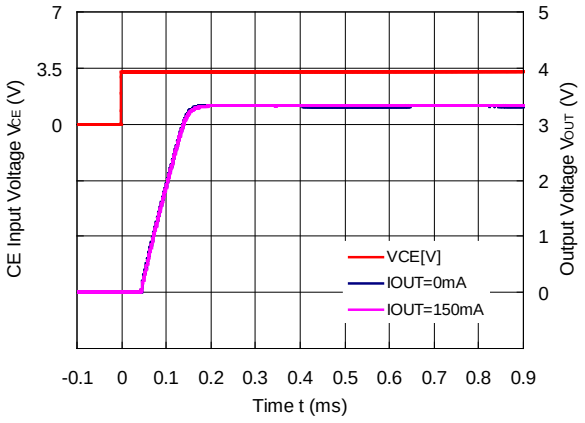
R1517x25xB/D, R1517x001C (C2 = 0.1 µF)



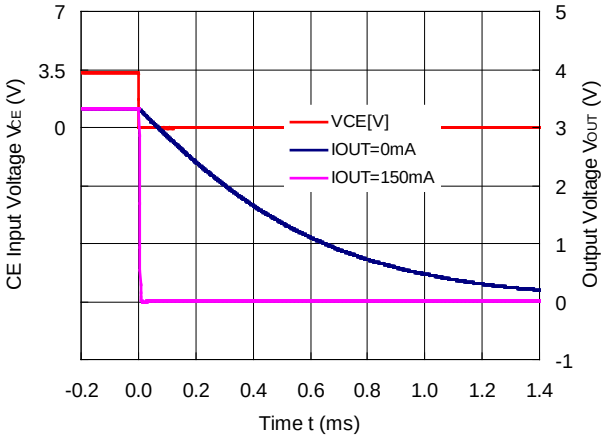
R1517x25xD (C2 = 0.1 µF)



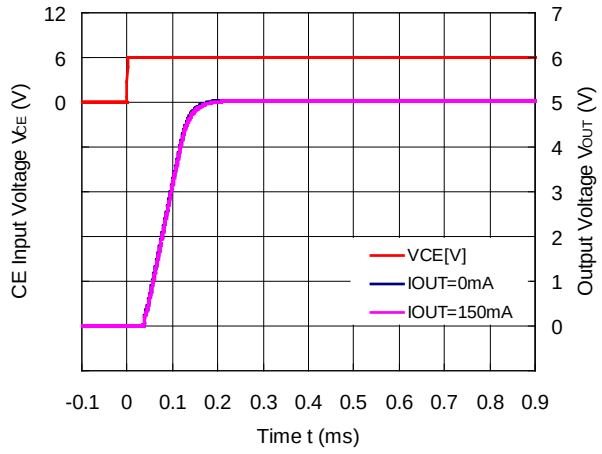
R1517x33xB/D (C2 = 0.1 µF)



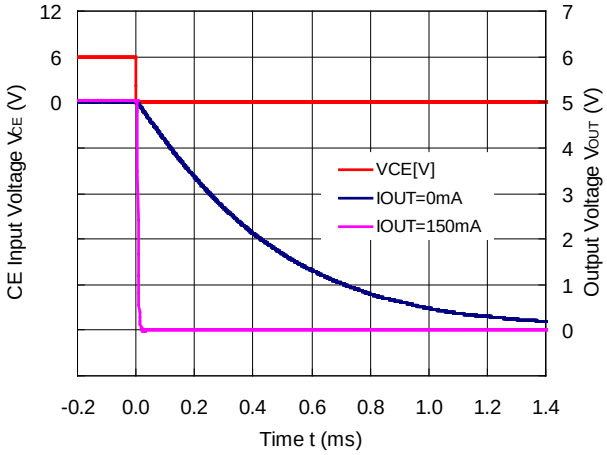
R1517x33xD (C2 = 0.1 µF)



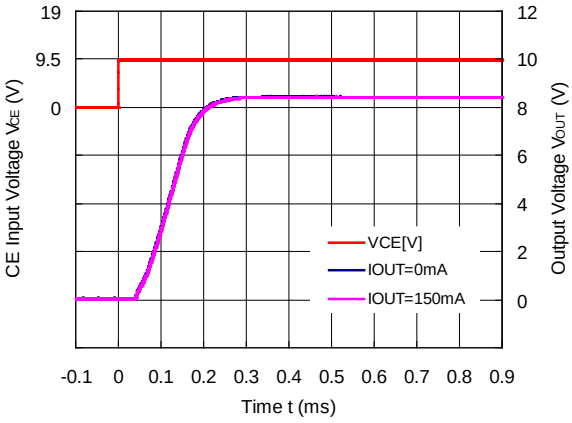
R1517x50xB/D (C2 = 0.1 µF)



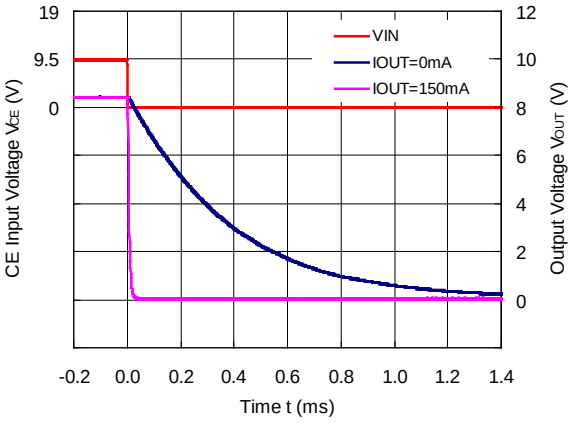
R1517x50xD (C2 = 0.1 µF)



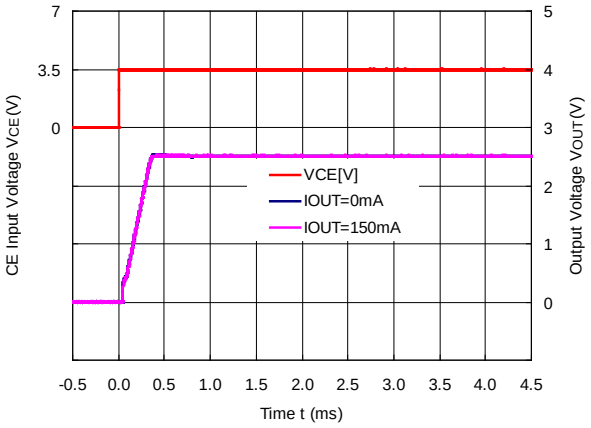
R1517x85xB/D (C2 = 0.1 µF)



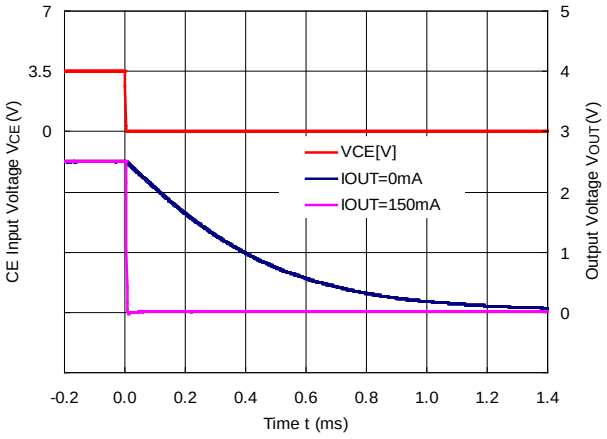
R1517x85xD (C2 = 0.1 µF)



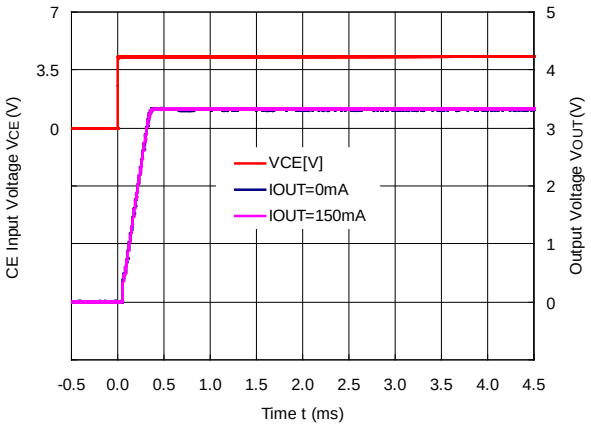
R1517x25xE/F (C2 = 0.1 µF, C_D = 1 nF)



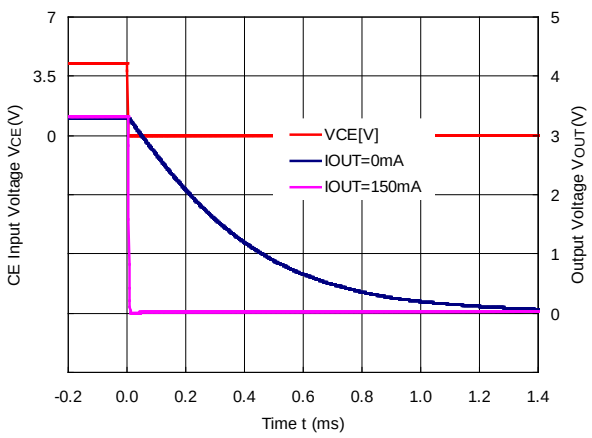
R1517x25xF (C2 = 0.1 µF, C_D = 1 nF)



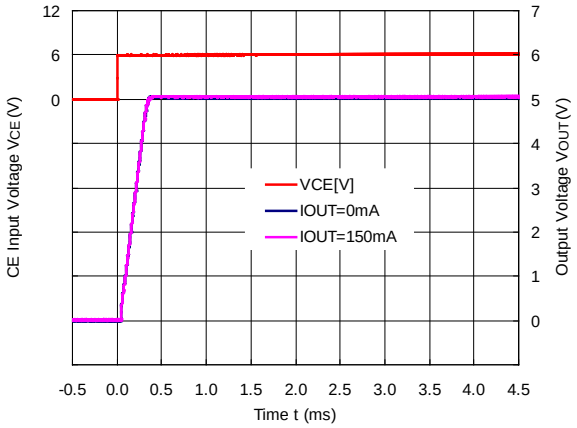
R1517x33xE/F (C2 = 0.1 µF, C_D = 1 nF)



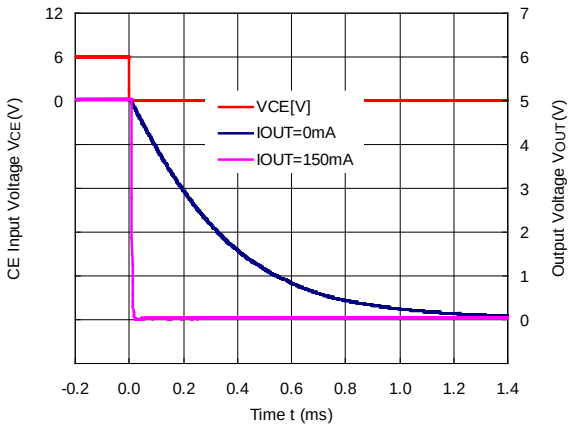
R1517x33xF (C2 = 0.1 µF, C_D = 1 nF)



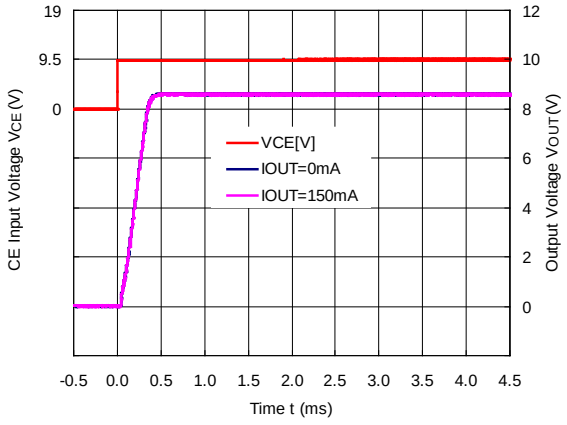
R1517x50xE/F (C2 = 0.1 µF, C_D = 1 nF)



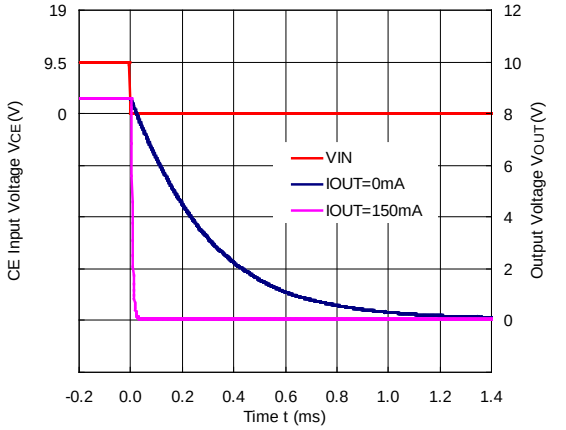
R1517x50xF (C2 = 0.1 µF, C_D = 1 nF)



R1517x85xE/F (C2 = 0.1 µF, C_D = 1 nF)

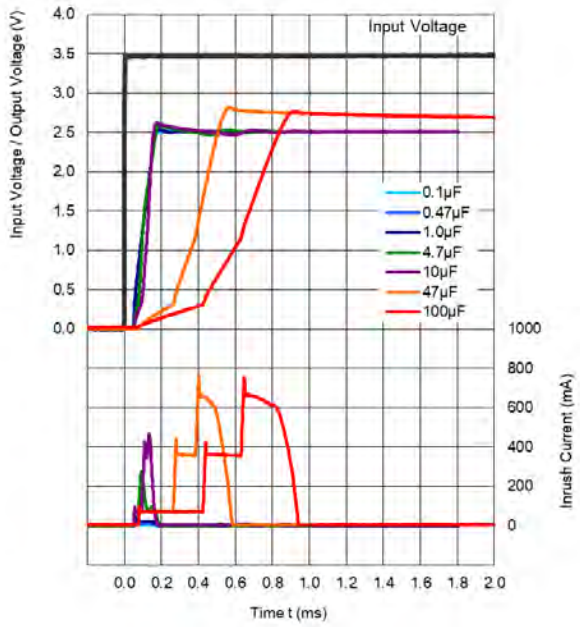


R1517x85xF (C2 = 0.1 µF, C_D = 1 nF)

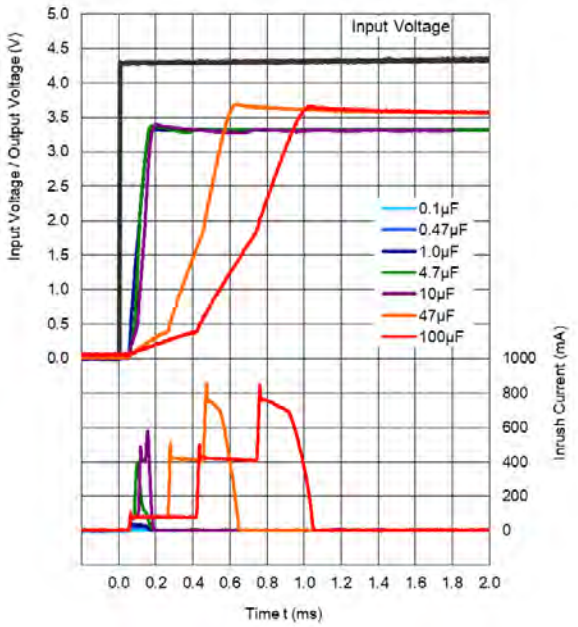


11) Inrush Current Prevention Circuit (Ta = 25°C, I_{OUT} = 1 mA)

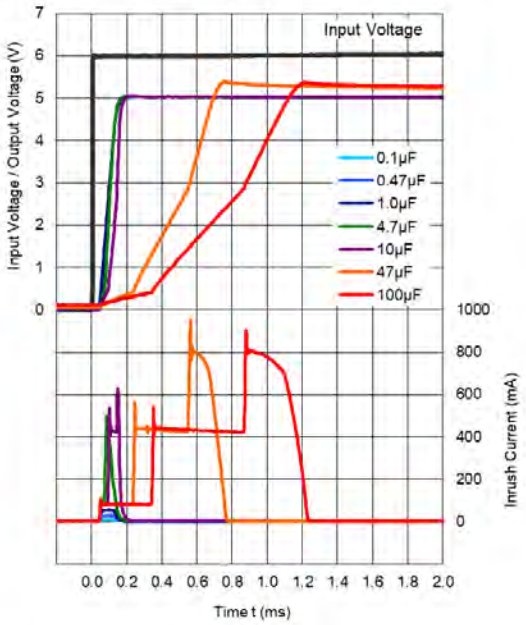
R1517x25xB/D, R1517x001C



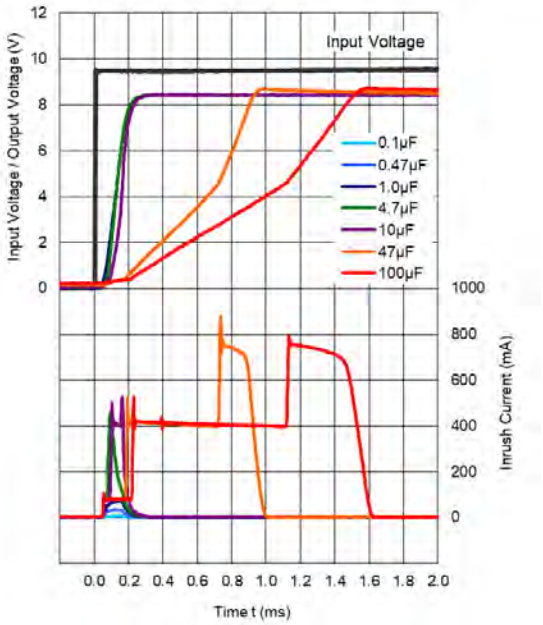
R1517x33xB/D



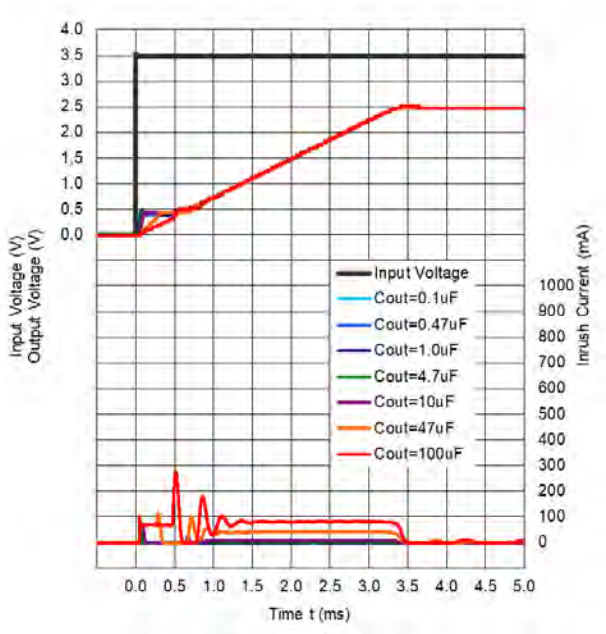
R1517x50xB/D



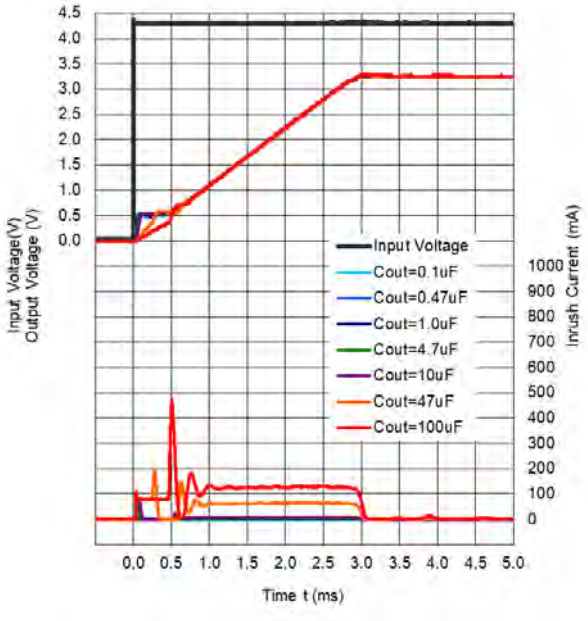
R1517x85xB/D



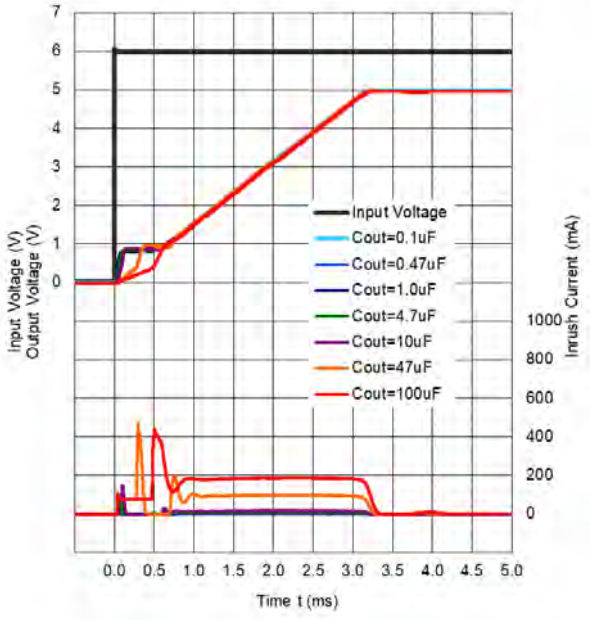
R1517x25xE/F (C_D = 10 nF)



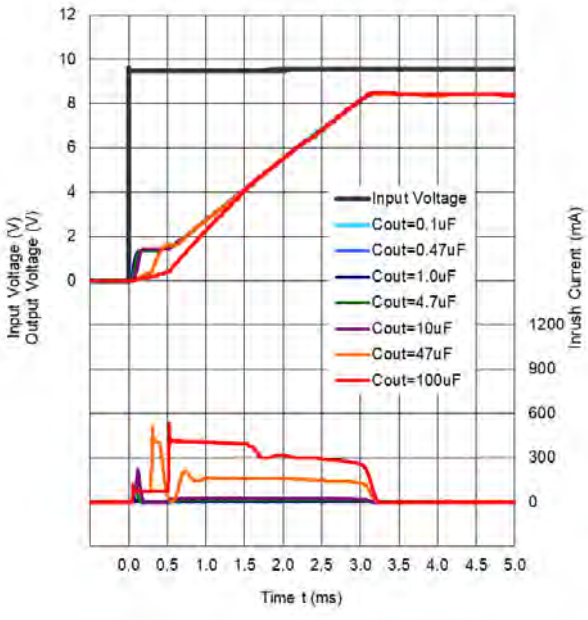
R1517x33xE/F (C_D = 10 nF)



R1517x50xE/F (C_D = 10 nF)



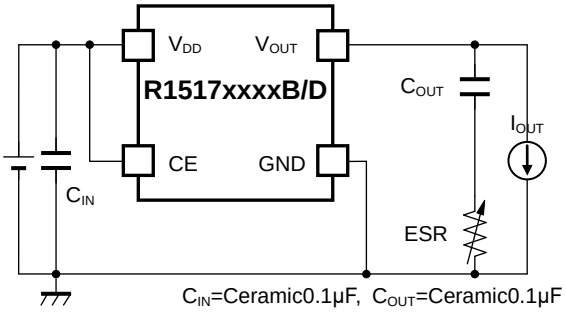
R1517x85xE/F (C_D = 10 nF)



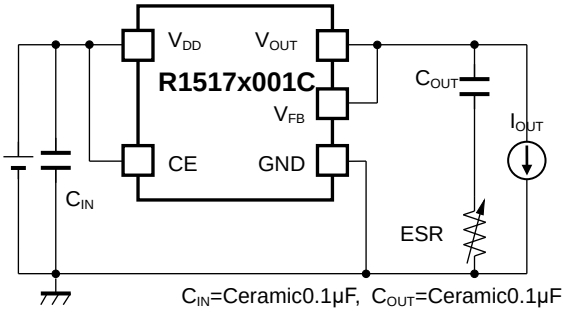
ESR vs. Output Current

It is recommended that a ceramic type capacitor be used for this device. However, other types of capacitors having lower ESR can also be used. The relation between the output current (I_{OUT}) and the ESR of output capacitor is shown below.

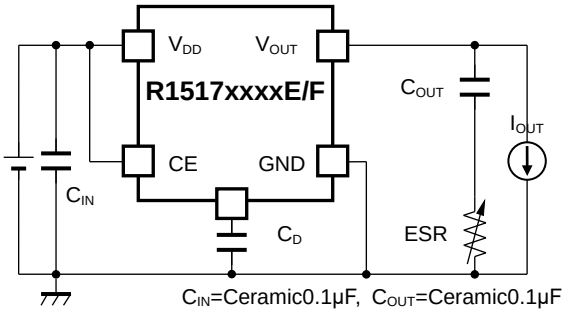
R1517xxxxB/D Test Circuit



R1517x001C Test Circuit



R1517xxxxE/F Test Circuit

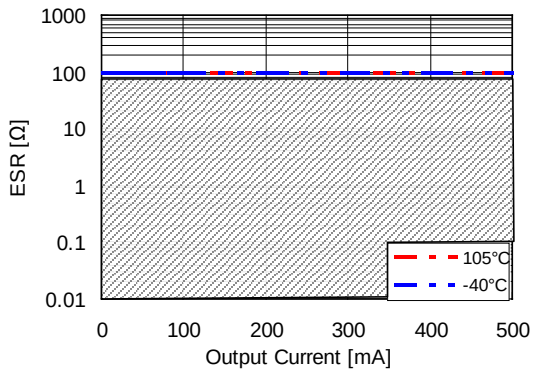


Measurement conditions

Frequency Band: 10 Hz to 2 MHz
Measurement Temperature: −40°C to 105°C
Hatched area: Noise level is 40 μV (average) or below
Capacitor: C1 = Ceramic 0.1 μF, C2 = 0.1 μF

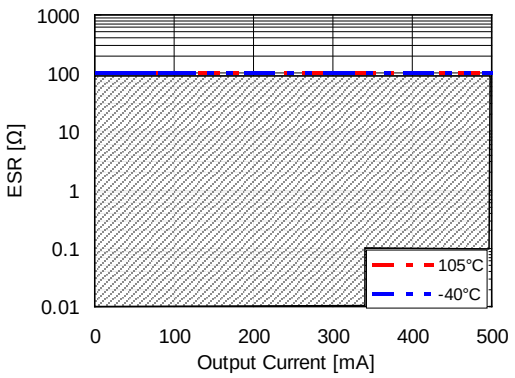
R1517x25xx Output Current I_{OUT} vs. ESR

Vin=2.5V to 36V



R1517x85xx Output Current I_{OUT} vs. ESR

Vin=8.5V to 36V



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